

RELAY SINCE 1988

TOWARD

Enrich your design.

Solid State Relay

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2016 Rev 2

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PhotoMOS-FET Relays
General-Purpose

PhotoMOS-FET Relays
Hi-A Grade $\geq 1A$

PhotoMOS-FET Relays
Hi-V Grade $\geq 600V$

PhotoMOS-FET Relays
Low Leakage Current

PhotoMOS-FET Relays
RF

PhotoMOS-FET Relays
Photo Coupler

PhotoMOS-FET Relays
Mos Driver

Solid State Relays

TC Series

Photo Triac



Features

- Compact DIP8 Pin Package
- High Isolation Voltage 5000VAC between input and output
- 600VDC peak blocking Voltage
- Be suitable for 110/220VAC power voltage
- Random-on & Zero-on types are available

Applications

- Power TRIAC driver
- Household appliance
- Solid State Relay



Order Code:

TC 2 09 R - 1
a b c d e

a : Model : TC=DIP 8 Pin Package Type
b : Output Voltage : 2 = 240VAC
c : Output Current : 09 = 0.9Amp ; 12 = 1.2Amp
d : Turn on Type : Nil = Zero-on ; R = Random - on
e : Option : Nil = Standard, 1 - 9 = Special Code

Absolute Maximum Rating:

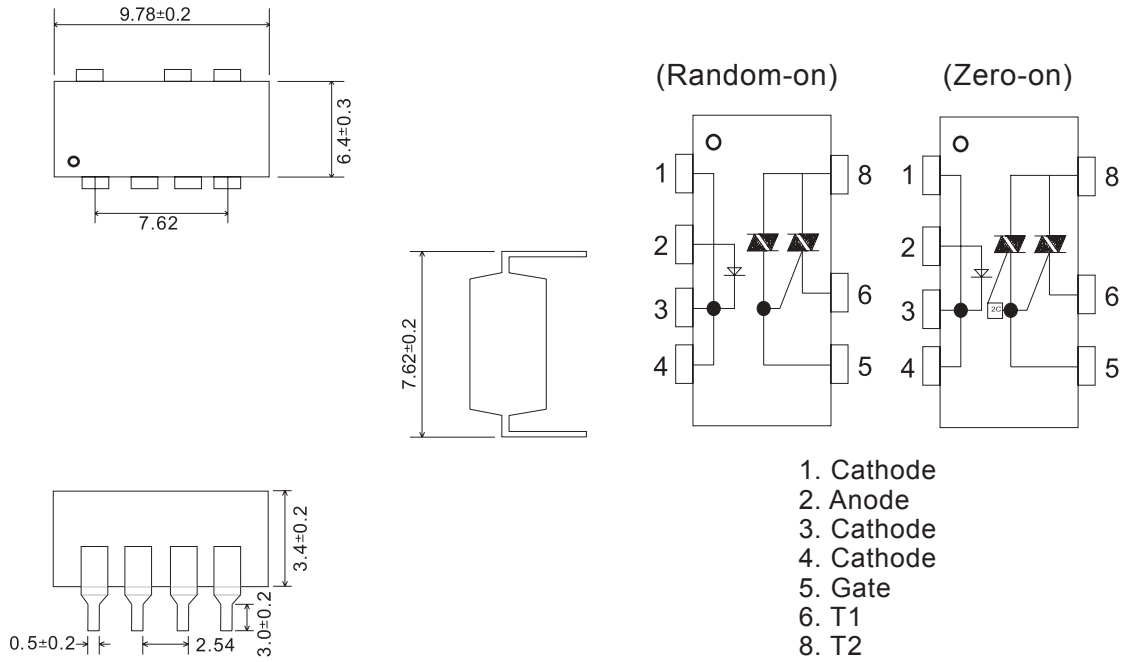
Item	Symbol	Rating		Unit	
		TC209(R)	TC212(R)		
Input	Forward Current	I _F	50	mA	
	Peak Forward Current	I _{FP}	1	A	
	Reverse Voltage	V _R	6	V	
Output	Off-state Output Voltage	V _{DRM}	600	VDC	
	On-state Output Current	I _{T(RMS)}	0.9	1.2	A
	Non-repeattive Sutge Current	I _{TSM}	9	12	A
I/O Isolation Voltage	V _{iso}	5000		VAC	
Operating Temperature	T _{opr}	-30~+85		°C	
Storage Temperature	T _{stg}	-40~+125		°C	

Electrical Characteristics:

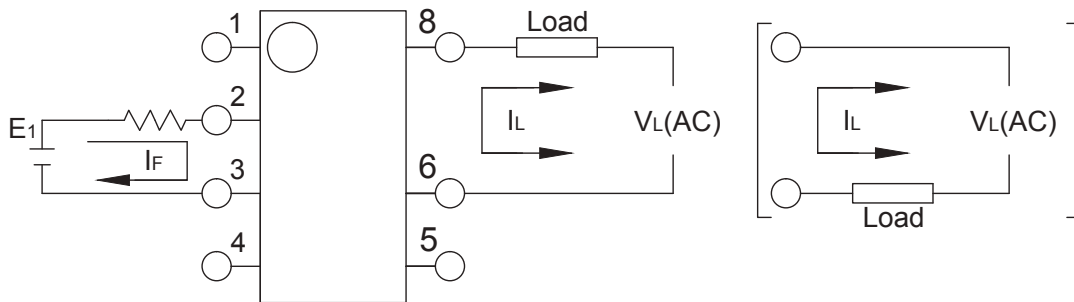
Item	Symbol	MIN.	Rating		MAX.	Unit	Conditions
			TC209(R)	TC212(R)			
Input	Forward Voltage	V _F	-	1.18	1.4	V	I _F =10mA
	Reverse Current	I _R	-	-	10	μA	V _R =6V
Output	Peak Leakage Current	I _{DRM}	-	-	100	μA	V _{DRM} =600V
	On-state Voltage	V _{TM}	-	1.3	1.1	V	I _T =Rated I _T
	Hold Current	I _H	-	-	25	mA	V _D =6V
	Rise rate of off-state	dv/dt	200	1000	-	V/μS	V _{DRM} =600V/√2
Minimum trigger current	I _{FT}	-	2	10	mA	V _D =6V	
Recovery Input Voltage	V _{FOFF}	0.5	-	-	V		
I/O Isolation Resistance	R _{iso}	50G	-	-	-		DC=500V
Turn-on Time (Random-on)	T _{ON}	-	8	100	μS		I _F =20mA
Turn-on Time (Zero-on)	T _{ON}	-	-	10	mS		-
Turn-off Time	T _{OFF}	-	-	10	mS		-

Note:Recommended trigger current is between 10mA and 20mA.

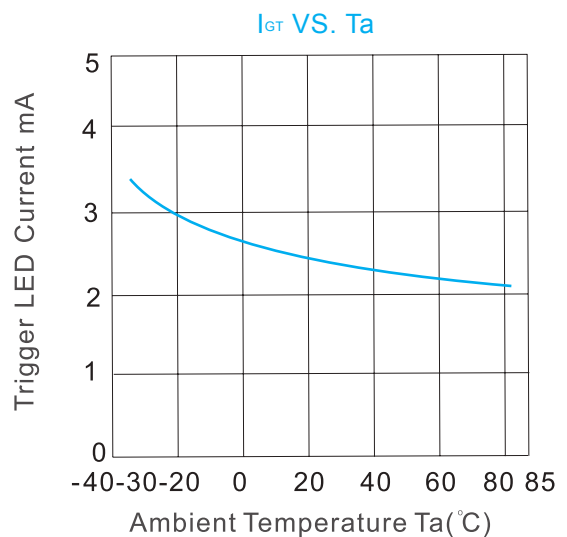
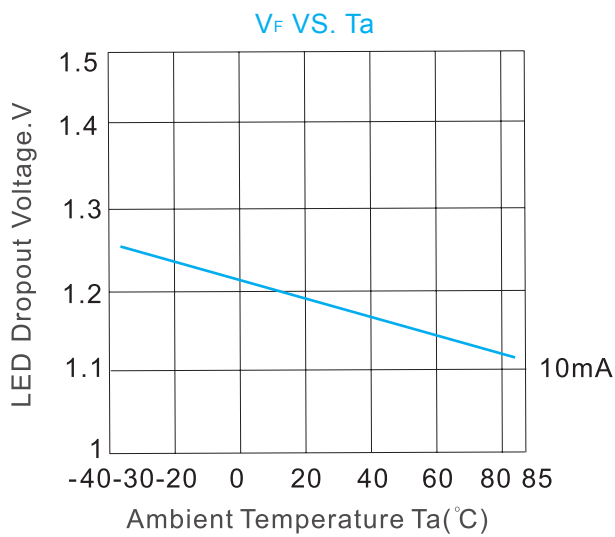
Dimensions : (Unit : mm)

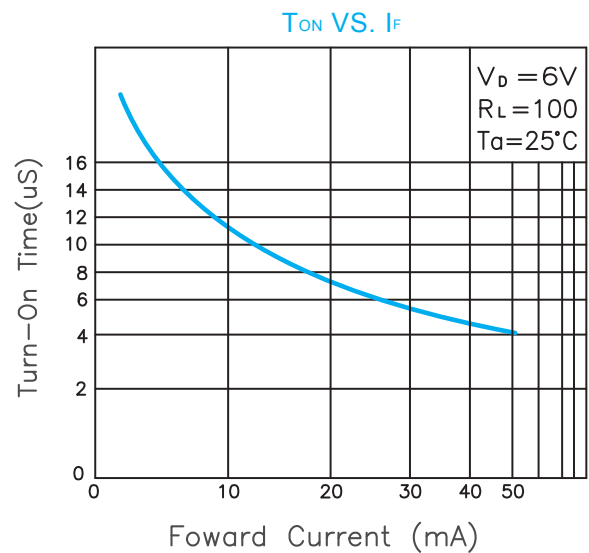
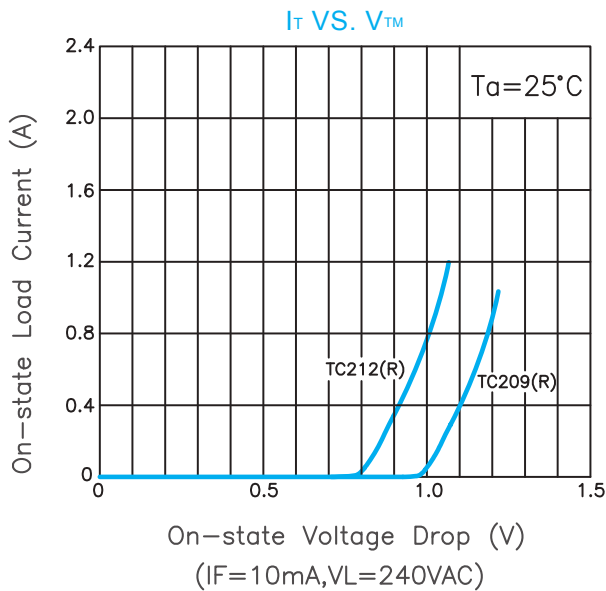
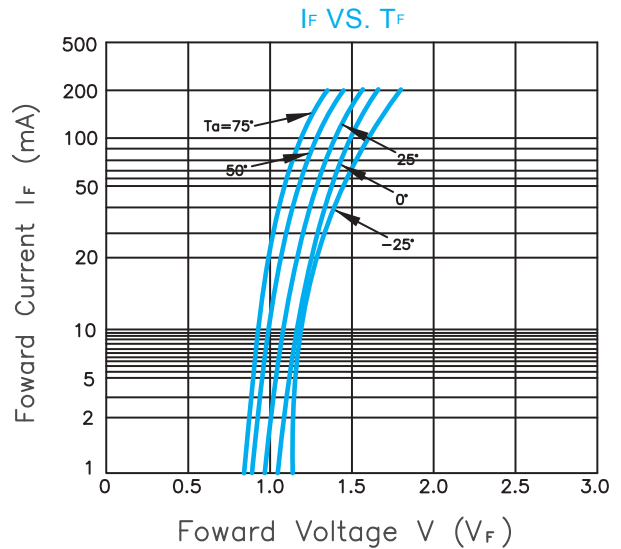
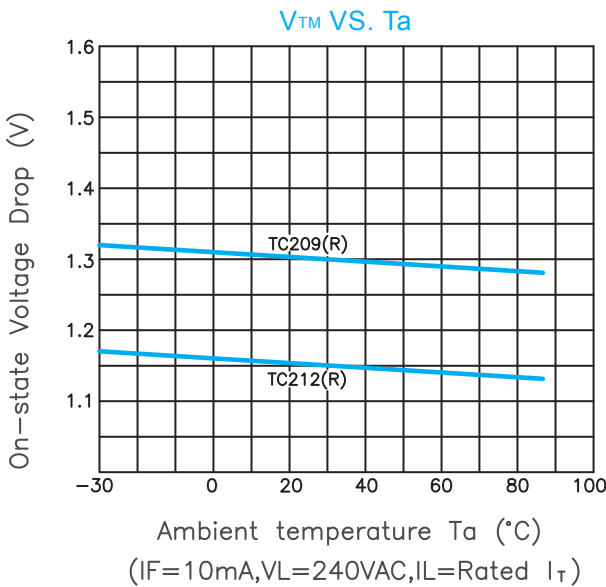
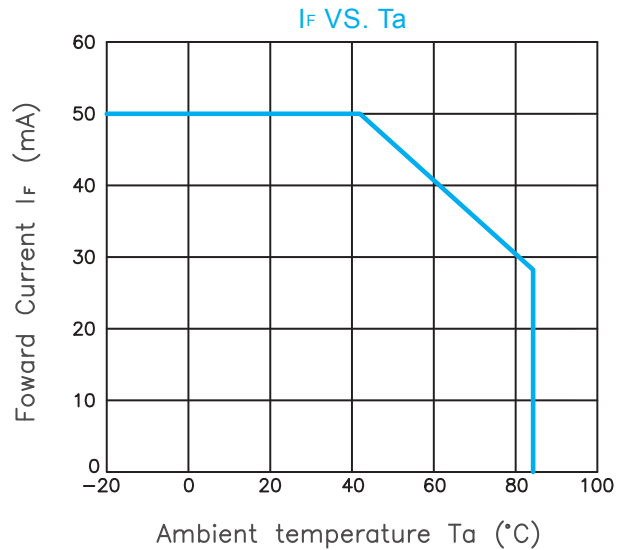
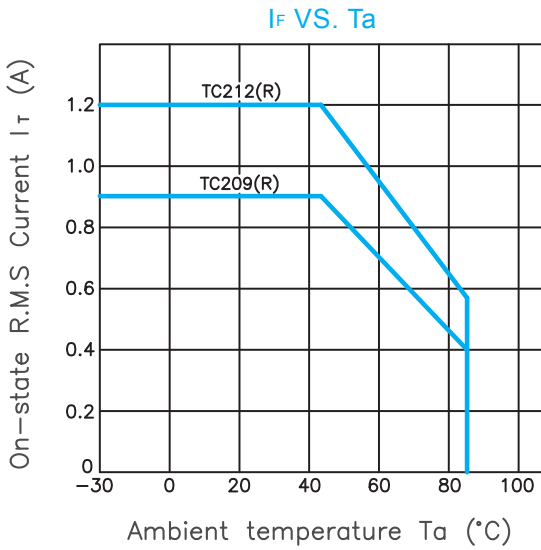


Wiring Diagram



REFERENCE DATA :





TM Series

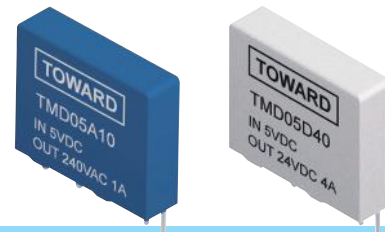
D/D·D/A·Load Current:1~4A

Features

- Optically isolated
- Ultra Slim and light weight, Sil terminals type for high density mounting :
--Size : 5(W) x 20(L) x 17(H) mm;
--Weight approximately 3.0g
- Low On-state resistance
- Low input power consumption
TTL and CMOS compatible control
- MOSFET output thyristor (DC output only)
- UL recognized.

Applications

- Temperature control system
- Industrial automatic control
- Lighting System
- Office appliances
- Factory appliances



Order Code:

TM D05 A10

a b c

a : Model : TM = Mini SIP Type

b : Input Voltage : D05 = DC5V ; D12 = DC12V ; D24 = DC24V

c : Output Current : A10 = AC1.0A ; D40 = DC4.0A

Specifications (AC Output)

Input Circuit

Type No	TMD05A10	TMD12A10	TMD24A10
Nominal Voltage	5VDC	12VDC	24VDC
Control Voltage Range	3~8VDC	8~18VDC	18~30VDC
Control Current	16mA	12mA	11mA
Min. Turn-off Voltage	1VDC		

Output Circuit

Max. Load Current	1.0 A
Min. Load Current	50 mA
Nominal Load Voltage	240 VAC
Load Voltage Range	24~265 VAC
Non-Repetitive Max. Voltage	600 V
Non-Repetitive Max. Peak Current	50 A
Max. Off-State Leakage Current	2.0 mA
Max. On-State Drop Voltage	1.5 V
Zero-On or Random-On	Random-On
Max. Turn-On Time	1 mS
Max. Turn-Off Time	1/2 Cycle + 1 mS
Max. Soldering Heat	220°C (10 Sec)
Insulation Resistance	1000MΩ , DC500V (for Input - Output)
Dielectric Strength (Between Input & Output)	2500V rms , 60 Sec (for Input - Output)
Operating Temperature Range	-30°C ~+80°C
Storage Temperature Range	-40°C ~+100°C

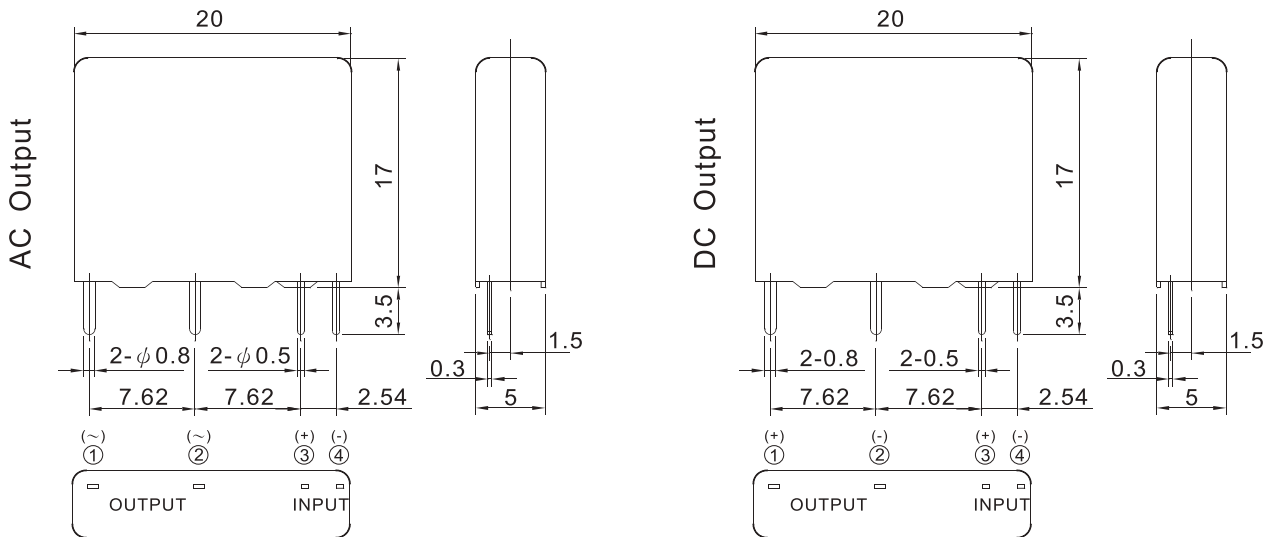


Specifications (DC Output)

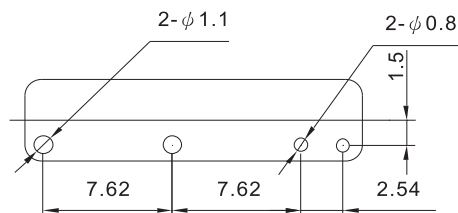
Input Circuit			
Type No	TMD05D40	TMD12D40	TMD24D40
Nominal Voltage	5VDC	12VDC	24VDC
Control Voltage Range	3~8VDC	8~18VDC	18~30VDC
Control Current	16mA	12mA	11mA
Min. Turn-off Voltage	1VDC		

Output Circuit	
Max. Load Current	4.0 A
Min. Load Current	1 mA
Nominal Load Voltage	60 VDC
Load Voltage Range	0~60 VDC
Max. Peak Current	7A (10ms)
Max. Off-State Leakage Current	<1 mA
Max. On-State Drop Voltage (2A)	0.24 V
Max. Turn-On Time	1 mS
Max. Turn-Off Time	0.1 mS
Operating Switching Frequency	10 Hz
Max. Soldering Heat	220°C (10 Sec)
Insulation Resistance	1000MΩ , DC500V (for Input-Output)
Dielectric Strength (Between Input & Output)	2500V rms , 60 Sec (for Input-Output)
Operating Temperature Range	-20°C ~+80°C
Storage Temperature Range	-25°C ~+80°C

Dimensions : (Unit : mm)



P.C.B. Layout (TOP View)



TG Series

D/A-Load Current : 2.0A

Features

- Small volume, SIP PCB mounting
- DC input, AC output
- Load current 2A
- Insulation voltage 2500V
- Internal RC circuit snubber

Applications

- Air conditioner
- Programmable control machine
- Greaser
- Automobile



Order Code:

TG D05 A20 3 R

a b c d e

a : Model : TG = DC Input, AC Output

b : Input Voltage : D05 = DC5V ; D12 = DC12V ; D24 = DC24V

c : Output Current : A = AC 2.0A

d : Output Voltage : NIL = 240VAC ; 3 = 380VAC

e : Turn - On Type : NIL = Zero - ON ; R = Random - ON

Specifications (AC Output)

Input Circuit			
Type No	TGD05****	TGD12****	TGD24****
Control Voltage Range	4~6 VDC Max.	9.6~14.4 VDC Max.	19.2~28.8 VDC Max.
Pick-Up Voltage	4VDC Max.	9.6VDC Max.	19.2VDC Max.
Input Current (nominal voltage)	Max. 13.1mA Min. 4.3mA	Max. 16.5mA Min. 5.4mA	Max. 15.4mA Min. 5.2mA
Release Voltage	1 VDC Min.	1 VDC Min.	1 VDC Min.
Input Internal Resistor	440Ω, ±20%	1KΩ, ±20%	2.2KΩ, ±20%

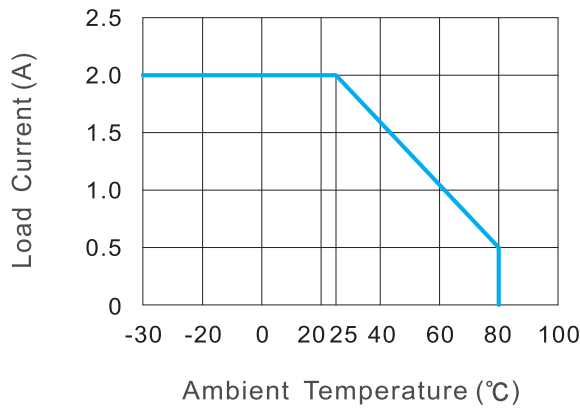
Output Characteristics (at 20°C)			
Type No	TGD**A20	TGD**A20R	TGD**A203
Load Current Range	0.1~2 Arms		
Operating Range	75~264 VAC		90~418 VAC
Non-Repetitive Max. Voltage	600 Vpk		800 Vpk
Non-Repetitive Max. Peak Current	25 Apk , 10ms		
Off-State Leakage Current	1.5mA		2.5mA
Turn-On Time (at 50Hz)	11 ms Max.	1ms Max.	11ms Max.
Turn-Off Time (at 50Hz)	11 ms Max.		
I ² t	3A ² s Max., 10ms		
Off State dv / dt	100 V/μs Min.		
Min. Power Factor	0.5, Rated Load		



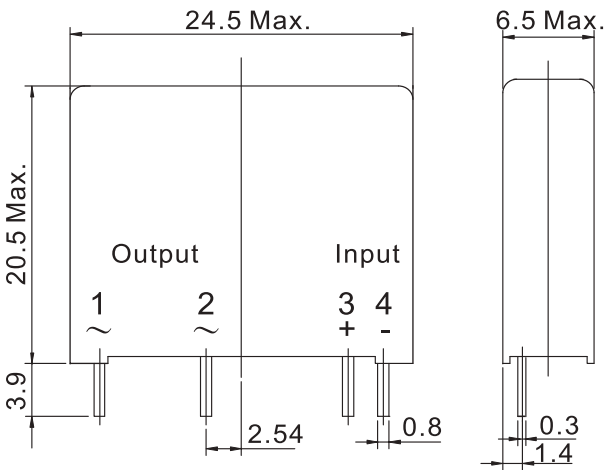
PhotoMOS-FET Relays
 General Purpose
 Hi-A Grade ≥ 1A
 Hi-V Grade ≥ 600V
 Low Leakage Current
 PhotoMOS-FET Relays
 RF
 Photo Coupler
 Mos Driver
 Solid State Relays

General Characteristics	
Insulation Resistance	1000 MΩ Min., 500 VDC
Dielectric Strength	2500 VAC Min., 60Sec
Vibration	10~555Hz, 0.75 mm , Amplitude , 5G
Shock	100 G
Operating Temperature Range	-30°C ~+80°C
Storage Temperature Range	-30°C ~+100°C
Humidity	45%~85%
Weight	6 g

Output Characterize



Dimensions : (Unit : mm)



Bottom View

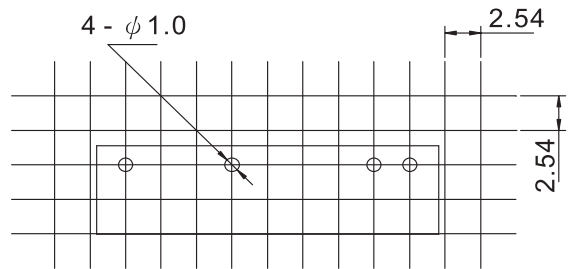
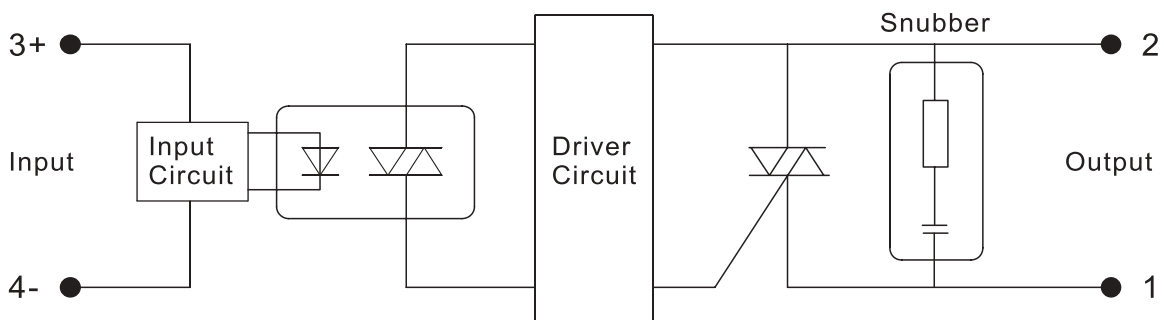


Photo - Triac



TMC Series

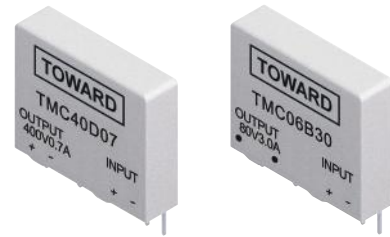
D/D·D/A·Load current:0.5~4.0A

Features

- Optically isolated
- Ultra Slim and light weight, Sil terminals type for high density mounting :
 - Size:5(W) x 20(L) x 17(H) mm;
 - Weight:approximately 3.0g
- Low On-state resistance
- Low input power consumption
- MOSFET output thyristor

Applications

- Temperature control system
- Industrial automatic control
- Lighting system
- Office appliances
- Factory appliances



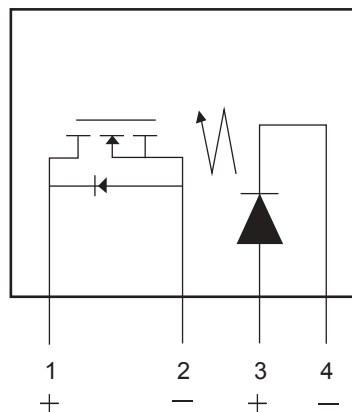
Order Code:

TMC 40 D 07

a b c d

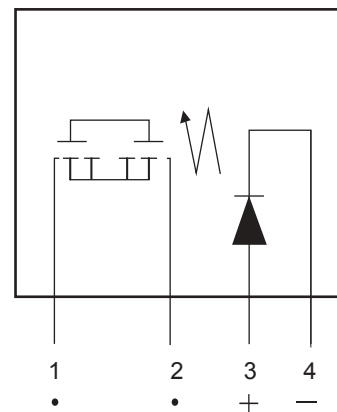
a : Model : TMC = Mini SIP Type, Current Input
 b : Output Voltage : 06 = 60V ; 10 = 100V ; 20 = 200V ; 40 = 400V
 c : Output Type : B = AC / DC Type, Current Input
 d : Output Current : 05 = 0.5A, 07 = 0.7A, 10 = 1.0A, 15 = 1.5A,
 20 = 2.0A, 28 = 2.8A, 30 = 3.0A, 40 = 4.0A

Terminal Identification



DC Type

Pin1: DC Output +
 Pin2: DC Output -
 Pin3: DC Voltage input +
 Pin4: DC Voltage input -



AC/DC Type

Pin1: AC/DC Output •
 Pin2: AC/DC Output •
 Pin3: DC Voltage input +
 Pin4: DC Voltage input -

Rating

AC/DC Type 1) Absolute Maximum Ratings (Ambient Temperature 25°C)



Item		Symbol	06B30	10B20	20B10	40B05	Remarks
Input	LED Forward Current	I _F	50mA				
	LED Reverse Voltage	V _R	5V				
	Peak Forward Current	I _{FP}	1A				f=100Hz.Duty factor=0.1%
	Power Dissipation	P _{IN}	75mW				
output	Load Voltage (Peak AC)	V _L	60V	100V	200V	400V	
	Continuous Load Current (Peak AC)	I _L	3.0A	2.0A	1.0A	0.5A	
	Peak Load Current	I _{PEAK}	9.0A	6.0A	3.0A	1.5A	100mS (1shot)
	Power Dissipation	P _{OUT}	1.6W				
Total Power Dissipation		P _T	1.6W				
I/O Breakdown Voltage		V _{I/O}	2500VAC				
Operating Temperature		T _{OPR}	-40°C ~+85°C				
Storage Temperature		T _{STG}	-40°C ~+100°C				

2) Electrical Specifications (Ambient Temperature 25°C)

Item		Symbol	06B30	10B20	20B10	40B05	Remarks	
Input	LED Operate Current	Typical	1.0mA				I _L =100mA V _L =10V	
		Maximum	3.0mA					
	LED Turn Off Current	Typical	0.5mA				I _L =100mA V _L =10V	
		Maximum	0.3mA					
	LED Dropout Voltage	Typical	1.4V				I _F =50mA	
		Maximum	1.7V					
output	On-Resistance	Typical	0.09Ω	0.14Ω	0.5Ω	2.4Ω	I _F =10mA I _L =Max Within 1 Sec on time	
		Maximum	0.18Ω	0.28Ω	1.0Ω	3.6Ω		
	Off-State Leakage Current	Maximum	10 μA				I _F =0mA V _L =Max	
Others	Switching Speed	Turn-On Time	Typical	2.2mS	2.4mS	1.5mS	1.4mS	I _F =10mA I _L =100mA V _L =10V
			Maximum	5.0mS				
		Turn-Off Time	Typical	0.1mS	0.1mS	0.1mS	0.1mS	I _F =10mA I _L =100mA V _L =10V
			Maximum	3.0mS				
	I/O Capacitance	Typical	0.8pF				f=1MHz	
		Maximum	2.0pF					
	I/O Insulation Resistance	Maximum	R _{I/O}	1000MΩ				500VDC
Maximum Operating Speed	Maximum	-	0.5cps				I _F =10mA Duty Fator=50% I _L =Max, V _L =Max	

DC Type

1) Absolute Maximum Ratings (Ambient Temperature 25°C)

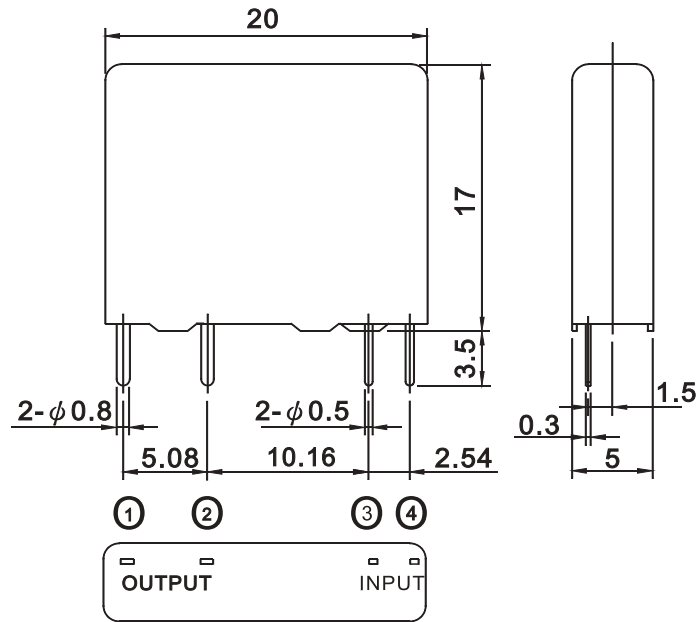
Item		Symbol	06D40	10D28	20D15	40D07	Remarks
Input	LED Forward Current	I _F	50mA				
	LED Reverse Voltage	V _R	5V				
	Peak Forward Current	I _{FP}	1A				f=100Hz.Duty factor=0.1%
	Power Dissipation	P _{IN}	75mW				
output	Load Voltage (Peak AC)	V _L	60V	100V	200V	400V	
	Continuous Load Current (Peak AC)	I _L	3.0A	2.0A	1.0A	0.5A	
	Peak Load Current	I _{PEAK}	9.0A	6.0A	3.0A	1.5A	100mS (1shot)
	Power Dissipation	P _{OUT}	1.6W				
Total Power Dissipation		P _T	1.6W				
I/O Breakdown Voltage		V _{I/O}	2500VAC				
Operating Temperature		T _{OPR}	-40°C ~+85°C				
Storage Temperature		T _{STG}	-40°C ~+100°C				

2) Electrical Specifications (Ambient Temperature 25°C)

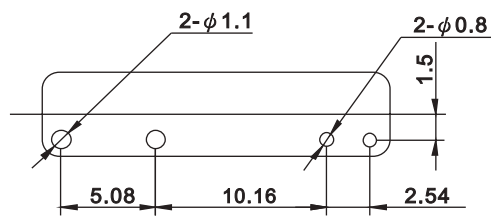
Item		Symbol	06D40	10D28	20D15	40D07	Remarks	
Input	LED Operate Current	Typical	1.0mA				I _L =100mA V _L =10V	
		Maximum	3.0mA					
	LED Turn Off Current	Typical	0.5mA				I _L =100mA V _L =10V	
		Maximum	0.3mA					
	LED Dropout Voltage	Typical	1.4V				I _F =50mA	
		Maximum	1.7V					
output	On-Resistance	Typical	0.045Ω	0.07Ω	0.25Ω	1.2Ω	I _F =10mA I _L =Max Within 1 Sec on time	
		Maximum	0.09Ω	0.14Ω	0.5Ω	1.8Ω		
	Off-State Leakage Current	Maximum	10 μA				I _F =0mA V _L =Max	
Others	Switching Speed	Turn-On Time	Typical	1.3mS	2.0mS	1.0mS	0.9mS	I _F =10mA I _L =100mA V _L =10V
			Maximum	5.0mS				
		Turn-Off Time	Typical	0.1mS	0.1mS	0.1mS	0.1mS	I _F =10mA I _L =100mA V _L =10V
			Maximum	3.0mS				
	I/O Capacitance	Typical	0.8pF				f=1MHz	
		Maximum	2.0pF					
	I/O Insulation Resistance		Maximum	1000MΩ				500VDC
Maximum Operating Speed		Maximum	0.5cps				I _F =10mA Duty Fator=50% I _L =Max, V _L =Max	



Dimensions : (Unit : mm)



P.C.B. Layout (TOP View)



Note: Recommended trigger current is between 10mA and 20mA.

PhotomOS-FET Relays
General Purpose
Hi-A Grade ≥ 1A
Hi-V Grade ≥ 600V
Low Leakage Current
RF
Photo Coupler
Mos Driver
Solid State Relays

TMV Series

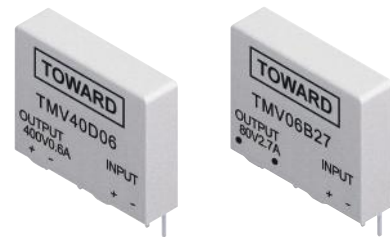
D/D·D/A·Load Current:0.45~3.6A

Features

- Optically isolated
- Ultra Slim and light weight, Sil terminals type for high density mounting :
--Size : 5(W) x 20(L) x 17(H) mm;
--Weight : approximately 3.0g
- Low On-state resistance
- Low input power consumption
- MOSFET output thyristor

Applications

- Temperature control system
- Industrial automatic control
- Lighting system
- Office appliances
- Factory appliances



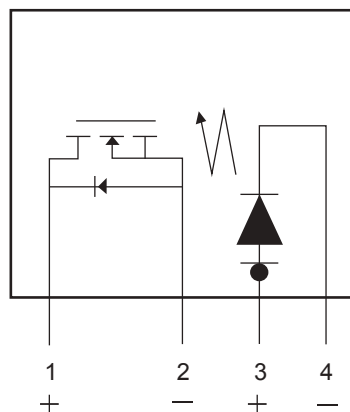
Order Code:

TMV 40 D 06

a b c d

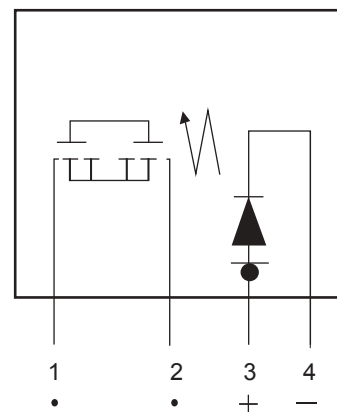
a : Model : TMV = Mini SIP Type, Voltage Input
 b : Output Voltage : 06 = 60V ; 10 = 100V ; 20 = 200V ; 40 = 400V
 c : Output Type : B = AC / DC Type, D = DC Type
 d : Output Current : 04 = 4.5A, 06 = 0.6A, 09 = 0.9A, 11 = 1.1A,
 18 = 1.8A, 25 = 2.5A, 27 = 2.7A, 36 = 3.6A

Terminal Identification



DC Type

Pin1: DC Output +
 Pin2: DC Output -
 Pin3: DC Voltage input +
 Pin4: DC Voltage input -



AC/DC Type

Pin1: AC/DC Output •
 Pin2: AC/DC Output •
 Pin3: DC Voltage input +
 Pin4: DC Voltage input -

Rating

AC/DC Type 1) Absolute Maximum Ratings (Ambient Temperature 25°C)



Item		Symbol	06B27	10B18	20B09	40B04	Remarks
Input	Voltage range	V_{IN}	4~32V				
	Reverse Voltage	V_{RIN}	5V				
	Power Dissipation	P_{IN}	300mW				
output	Load Voltage (Peak AC)	V_L	60V	100V	200V	400V	
	Continuous Load Current (Peak AC)	I_L	2.7A	1.8A	0.9A	0.45A	
	Peak Load Current	I_{PEAK}	9.0A	6.0A	3.0A	1.5A	100mS (1shot)
	Power Dissipation	P_{OUT}	1.6W				
Total Power Dissipation		P_T	1.6W				
I/O Breakdown Voltage		$V_{I/O}$	2500VAC				
Operating Temperature		T_{OPR}	-40°C ~+85°C				
Storage Temperature		T_{STG}	-40°C ~+100°C				

2) Electrical Specifications (Ambient Temperature 25°C)

Item		Symbol	06B27	10B18	20B09	40B04	Remarks	
Input	Operate Voltage	Typical	1.4V				$I_L=100mA$ $V_L=10V$	
		Maximum	4V					
	Turn Off Voltage	Typical	1.3V				$I_L=100mA$ $V_L=10V$	
		Maximum	0.8V					
Input current	Typical	I_{IN}	7.2mA				$V_{IN}=5V$	
	Typical							
output	On-Resistance	Maximum	0.09Ω	0.14Ω	0.5Ω	2.4Ω	$V_{IN}=5V$ $I_L=Max$ Within 1 Sec on time	
		Maximum	0.18Ω	0.28Ω	1.0Ω	3.6Ω		
Off-State Leakage Current		Typical	10 μA				$V_{IN}=5V$ $V_L=Max$	
Others	Switching Speed	Turn-On Time	Maximum	2.5mS	4.2mS	2.8mS	1.5mS	$V_{IN}=5V$ $I_L=100mA$ $V_L=10V$
			Typical	10mS				
		Turn-Off Time	Maximum	0.1mS	0.1mS	0.1mS	0.1mS	$V_{IN}=5V$ $I_L=100mA$ $V_L=10V$
			Typical	3.0mS				
	I/O Capacitance	Maximum	$C_{I/O}$	0.8pF				f=1MHz
		Maximum		2.0pF				
I/O Insulation Resistance		Maximum	1000MΩ				500VDC	
Maximum Operating Speed		Maximum	0.5cps				$V_{IN}=5V$, Duty Fator=50% $I_L \times V_L=200(VA)$	

DC Type

1) Absolute Maximum Ratings (Ambient Temperature 25°C)

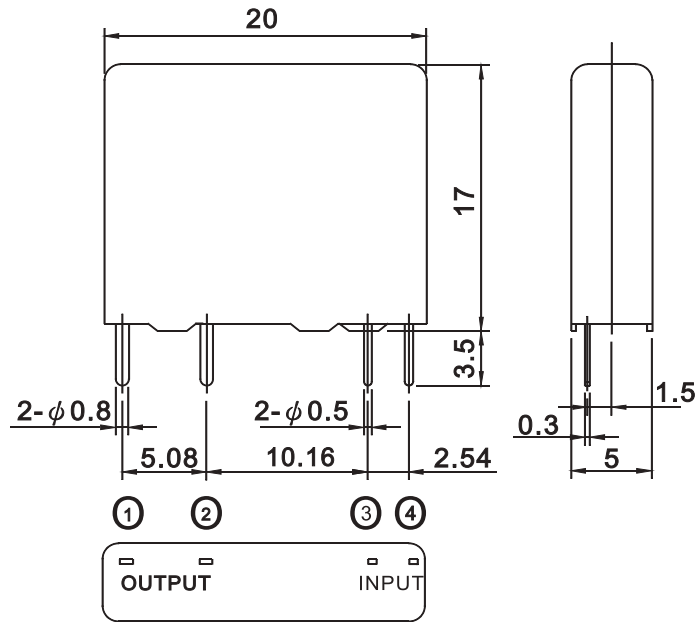
Item		Symbol	06D36	10D25	20D11	40D06	Remarks
Input	Voltage range	V_{IN}	4~32V				
	Reverse Voltage	V_{RIN}	5V				
	Power Dissipation	P_{IN}	300mW				
output	Load Voltage (Peak AC)	V_L	60V	100V	200V	400V	
	Continuous Load Current (Peak AC)	I_L	3.6A	2.5A	1.1A	0.6A	
	Peak Load Current	I_{PEAK}	9.0A	6.0A	3.0A	1.5A	100mS (1shot)
	Power Dissipation	P_{OUT}	1.35W				
Total Power Dissipation		P_T	1.35W				
I/O Breakdown Voltage		$V_{I/O}$	2500VAC				
Operating Temperature		T_{OPR}	-40°C ~+85°C				
Storage Temperature		T_{STG}	-40°C ~+100°C				

2) Electrical Specifications (Ambient Temperature 25°C)

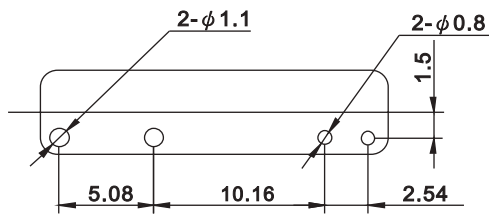
Item		Symbol	06D36	10D25	20D11	40D06	Remarks	
Input	Operate Voltage	Typical	1.4V				$I_L=100mA$ $V_L=10V$	
		Maximum	4V					
	Turn Off Voltage	Typical	1.3V				$I_L=100mA$ $V_L=10V$	
		Maximum	0.8V					
Input current	Typical	I_{IN}	7.2mA				$V_{IN}=5V$	
	Typical							
output	On-Resistance	Maximum	0.045Ω	0.07Ω	0.25Ω	1.2Ω	$V_{IN}=5V$ $I_L=Max$ Within 1 Sec on time	
		Maximum	0.09Ω	0.14Ω	0.5Ω	1.8Ω		
Off-State Leakage Current		Typical	10 μA				$V_{IN}=5V$ $V_L=Max$	
Others	Switching Speed	Turn-On Time	Maximum	1.5mS	2.5mS	1.5mS	1.0mS	$V_{IN}=5V$ $I_L=100mA$ $V_L=10V$
			Typical	10mS				
		Turn-Off Time	Maximum	0.1mS	0.1mS	0.1mS	0.1mS	$V_{IN}=5V$ $I_L=100mA$ $V_L=10V$
			Typical	3.0mS				
	I/O Capacitance		Maximum	0.8pF				f=1MHz
			Maximum	2.0pF				
I/O Insulation Resistance		Maximum	1000MΩ				500VDC	
Maximum Operating Speed		Maximum	0.5cps				$V_{IN}=5V$, Duty Fator=50% $I_L \times V_L=200(VA)$	



Dimensions : (Unit : mm)



P.C.B. Layout (TOP View)



PhotoMOS-FET Relays
General-Purpose

PhotoMOS-FET Relays
Hi-A Grade ≥ 1A

PhotoMOS-FET Relays
Hi-V Grade ≥ 600V

PhotoMOS-FET Relays
Low Leakage Current

PhotoMOS-FET Relays
RF

PhotoMOS-FET Relays
Photo Coupler

PhotoMOS-FET Relays
Mos Driver

Solid State Relays

TS Series

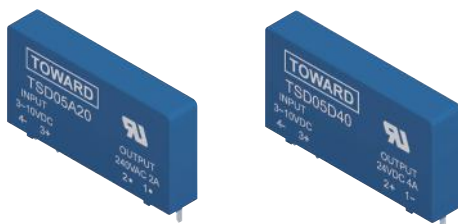
D/D·D/A·Load Current:2.0~4.0A

Features

- Optically isolated
- Low On-state resistance
- Low input power consumption
- MOSFET output thyristor(VDC)

Applications

- Household appliance
- Temperature control system
- Industrial automatic control
- Lighting system
- Office appliances
- Factory appliances



Order Code:

TS D05 A20

a b c

a : Model : TS = SLIM Type

b : Input Voltage : D05 = DC5V ; D12 = DC12V ;
D24 = DC24V ; D48 = DC48V ;

c : Output Current : A20 = AC2.0A ; D25 = DC2.5A ; D40 = DC4.0A

Specifications (AC Output)

Input Circuit

Type No	TSD05A20	TSD12A20	TSD24A20
Nominal Voltage	5VDC	12VDC	24VDC
Control Voltage Range	3~10VDC	7~20VDC	18~30VDC
Control Current	12mA	10mA	7.7mA
Release Voltage	1VDC		
Input Internal Resistor	300Ω	1010Ω	3000Ω

General Characteristics

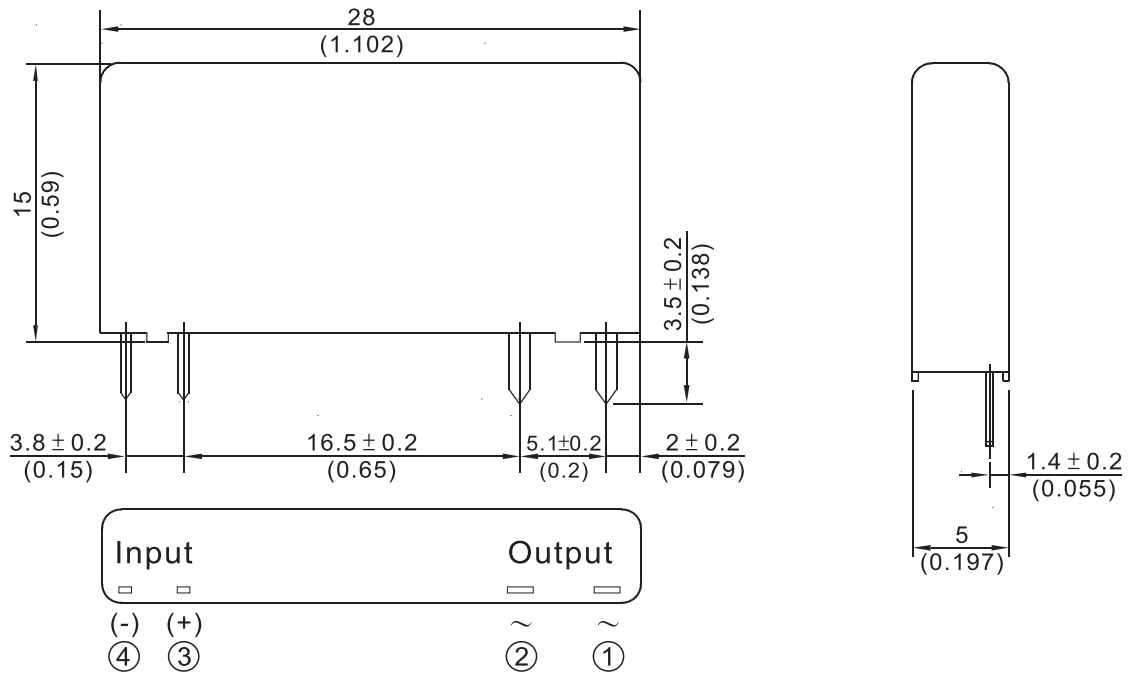
Operating Temperature Range	-20°C ~+80°C
Storage Temperature Range	-40°C ~+100°C
Input - Output Isolation	3.5KV rms, 1Minute (for Input-Output)
Max. Soldering Heat	260°C (10 Sec)
Weight	4g



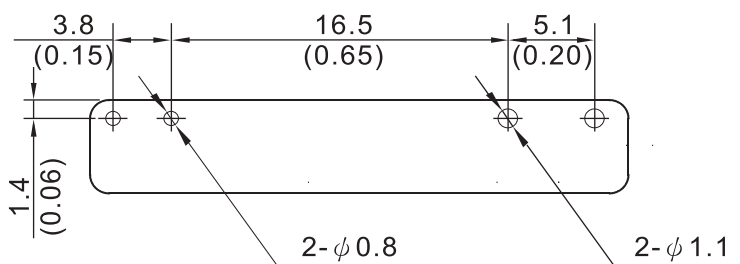
PhotoMOS-FET Relays
 General-Purpose
 Hi-A Grade $\geq 1A$
 PhotoMOS-FET Relays
 Hi-V Grade $\geq 600V$
 PhotoMOS-FET Relays
 Low Leakage Current
 RF
 PhotoMOS-FET Relays
 Photo Coupler
 Mos Driver

Output Characteristics (at 20°C)	
Load Voltage	240 Vrms
Operating Range	12~280 Vrms
Peak Voltage (Clamping Voltage)	600 V
Nominal Current	2A
Non-Repetitive Overload Current	80A
On-State Drop Voltage	1.2V
Off-State Leakage Current	<1.5mA
Min. Load Current	50mA
Turn-On Time (at Nominal Voltage)	100 μ s(Random-on)/10ms(Zero-on)
Turn-Off Time (at Nominal Voltage)	10 ms
Operating Switching Frequency	47~400Hz
Off-State dv/dt	500V/ μ s
RC Sunbber	10nF,100 Ω

Dimensions : (Unit : mm)



P.C.B. Layout (TOP View)



Specifications (DC Output)

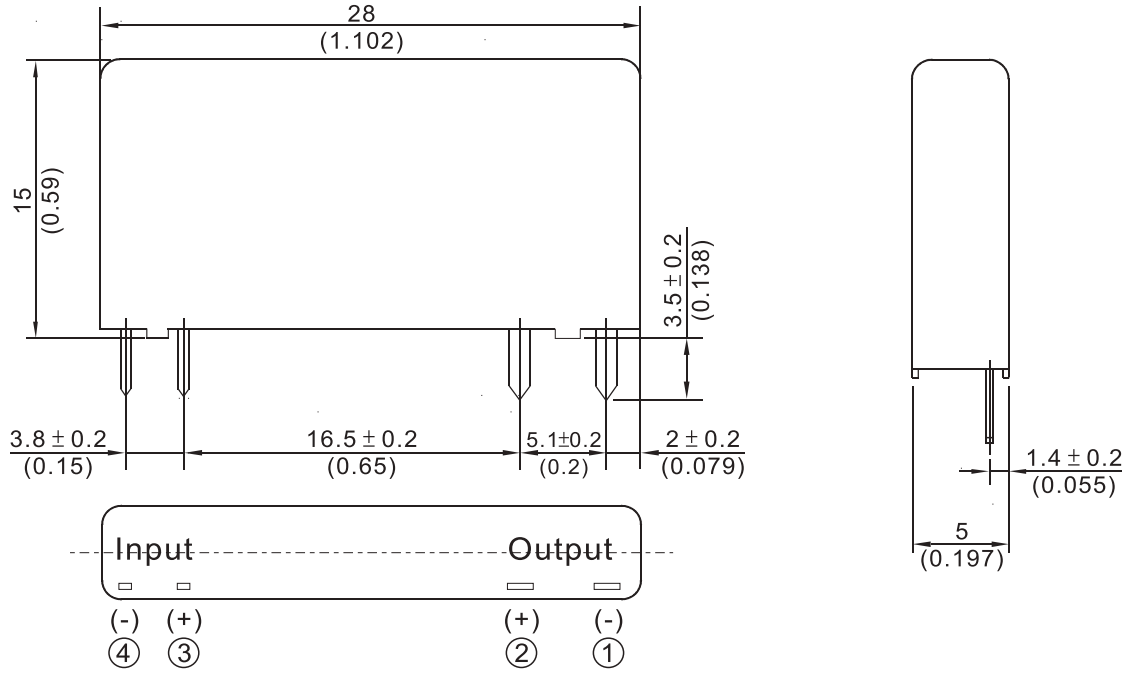
Input Circuit				
Type No (2.5A/48VDC)	TSD05D25	TSD12D25	TSD24D25	TSD48D25
Nominal Voltage	5VDC	12VDC	24VDC	48VDC
Control Voltage Range	3~10VDC	7~20VDC	18~30VDC	38~58VDC
Control Current	12mA	10mA	7.7mA	4.4mA
Release Voltage	1.8V	3.6V	8.3V	8.3V
Input Internal Resistor	320Ω	1070Ω	3000Ω	10800Ω
Type No (4A/24VDC)	TSD05D40	TSD12D40	TSD24D40	TSD48D40
Nominal Voltage	5VDC	12VDC	24VDC	48VDC
Control Voltage Range	3~10VDC	7~20VDC	18~30VDC	38~58VDC
Control Current	12mA	10mA	7.7mA	4.4mA
Release Voltage	1.8V	3.6V	8.3V	8.3V
Input Internal Resistor	320Ω	1070Ω	3000Ω	10800Ω

General Characteristics	
Operating Temperature Range	-20°C ~+80°C
Storage Temperature Range	-25°C ~+80°C
Input - Output Isolation	2.5KV rms, 1Minute (for Input-Output)
Max. Soldering Heat	260°C (10 Sec)
Weight	4g

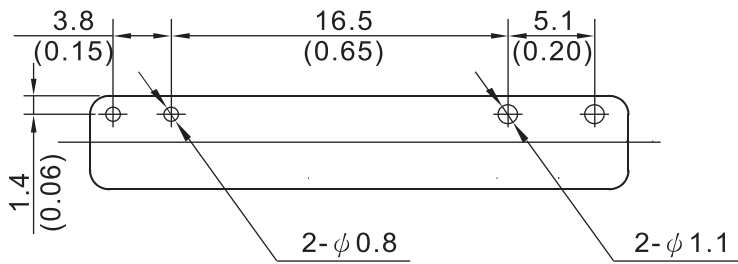
Output Characteristics (at 20°C)	TSD**D25	TSD**D40
Load Voltage	48V	24V
Operating Range	0~60V	0~32V
Nominal Current	2.5A	4A
Non-Repetitive Overload Current	6A	7A
On-State Drop Voltage (at IL=2A)	0.4V	0.24V
Static Output On-Resistance (at IL=2A)	200mΩ	120mΩ
Off-State Leakage Current	<1mA	<1mA
Minimum Load Current	1mA	1mA
Turn-On Time (at Nominal Voltage)	150 μs	150 μs
Turn-Off Time (at Nominal Voltage)	600 μs	600 μs
Operating Switching Frequency	10Hz	10Hz
Transient Voltage Suppressor	YES	YES
Breakdown Voltage	60V	36V
Peak Power Dissipation	600W	600W
Peak Voltage (Clamping Voltage)	100V	60V



Dimensions : (Unit : mm)



P.C.B. Layout (TOP View)



PhotoMOS-FET Relays
General-Purpose
Hi-A Grade ≥ 1A
Hi-V Grade ≥ 600V
Low Leakage Current
PhotoMOS-FET Relays
RF
Photo Coupler
Mos Driver

Solid State Relays

TNA Series

D/A·Load Current:2.0~6.0A

Features

- Optically isolated
- Low On-state resistance
- Low input power consumption
- TTL and CMOS compatible control



Applications

- Household appliance
- Temperature control system
- Industrial automatic control
- Lighting system
- Office appliances
- Factory appliances

Order Code:

TNA X XX

a b c

a : Model : TNA = DC Input, AC Output

b : Load Voltage Range : 2 = 24 - 280VAC, 4 = 24 - 480VAC

c : MAX Load Current : 02 = 2A, 03 = 3A, 04 = 4A, 05 = 5A, 06 = 6A

Specifications (AC Output)

Input Circuit

Control Voltage Range	3~32VDC
Pick-Up Voltage	3VDC MAX
Input Impedence	1.5k Ω
Must Turn-On Voltage	1VDC Max.
Max. Input Voltage	32VDC

Output Characteristics (at20°C)

Type No	202	203	204	205	206	402	404	405	406
Load Current Range (A)	2	3	4	5	6	2	4	5	6
Operating Range	24~280VAC					24~480VAC			
Non Repetitive Max. Voltage	600 Vpk					1200 Vpk			
Max. 1-CYCLE Peak Surge(A)	30	40	50	55	60	20	40	50	60
On State Drop Voltage	1.5 VAC	2 VAC							
Max. Off-State Leakage Current	5mA								
Turn - ON Time (at 50Hz)	1/2AC CYCLE								
Turn - OFF Time (at 50Hz)	1/2AC CYCLE								
Min. OFF-State dv/dt	100 V/ms			200 V/ms			500 V/ms		
Zero-On or Random-On	Zero-On								

TND Series

D/D·Load Current:2.0~4.0A

Features

- Optically isolated
- Low On-state resistance
- Low input power consumption
- TTL and CMOS compatible control



Applications

- Household appliance
- Temperature control system
- Industrial automatic control
- Lighting system
- Office appliances
- Factory appliances

Order Code:

TND X XX

a b c

a : Model : TND = DC Input, DC Output

b : Load Voltage Range : 0.6 = 3 - 60VDC

c : MAX Load Current : 02 = 2A, 04 = 4A

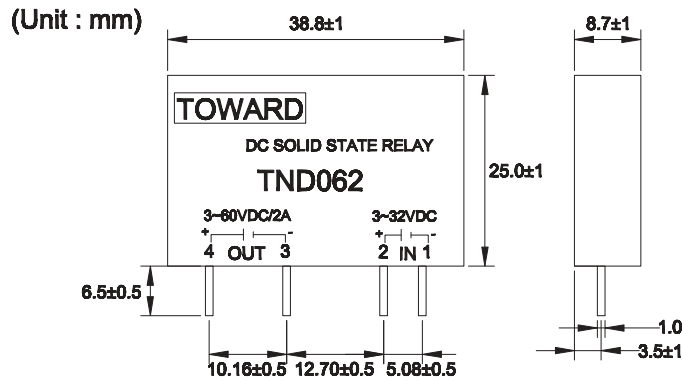
Specifications (DC Output)

Input Circuit		
Type No	TND 062	TND 064
Nominal Voltage	3 VDC	
Control Voltage Range	3~32VDC	
Input Impedence	1.5k Ω	
Min Turn-Off Voltage	1VDC	
Output Circuit		
Max.Load Current	2A	4A
Nominal Voltage Range	60 VDC	
Load Voltage Range	3~60 VDC	
Max. Peak Current	10A	8.5A
Max. Off-State Leakage Current	1mA	
Max. ON-State Drop Voltage	1.2V	
Max. Turn - ON Time	2ms	
Max. Turn - OFF Time	2ms	
Min Blocking Voltage	80 VDC	
Capacitance In-Out	15 pF	
Min. OFF-State dv/dt	200V/ μ Sec	

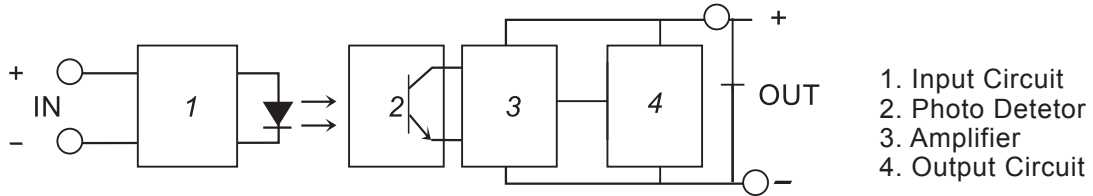


General Characteristics		
Type No.	TND 062	TND 064
Dielectric Strength Input-Output	2500 V.r.m.s.	
Isolate Impedence	10 ⁹ Ω	
Operating Temperature Range	-20°C ~+80°C	
Storage Temperature Range	-30°C ~+100°C	
Weight	10g Max.	12g Max.

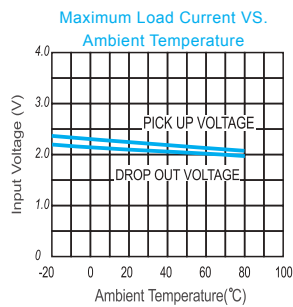
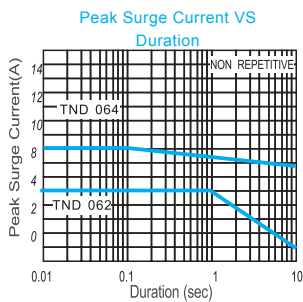
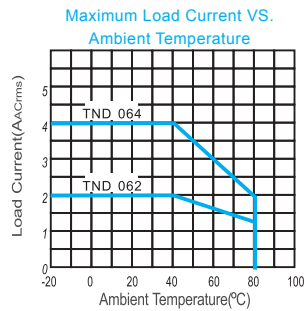
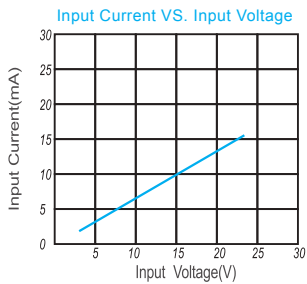
Dimensions : (Unit : mm)



EQUIVALENT CIRCUIT



CHARACTERISTIC CURVES



TPA Series

D/A·Load Current : 5.0A

Features

- TTL logic circuit compatible input
- Zero voltage on
- Zero current off
- Load current 5A



Order Code:

TPA M 2 5

a b c d

a : Model : TPA = DC Input, AC Output

b : Input Voltage : M = 3~14 VDC ; H = 10~32 VDC ; L = 3~32 VDC

c : Output Voltage : 2 = 220 VAC ; 3 = 380 VAC

d : Rated Current : 5 = 5A

Specifications (DC Output)

Input Circuit			
Type	TPAM*5	TPAH*5	TPAL*5
Input Voltage Range	3~14 VDC	10~32 VDC	3~32 VDC
Input Current	5~25 mA	5~16 mA	5~15 mA
Min Release Voltage	1VDC	5 VDC	1VDC

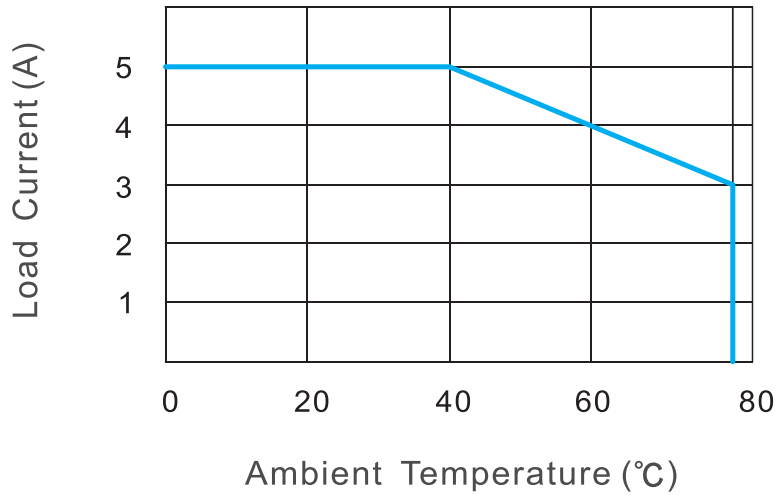
Output Characteristics(at20°C)		
Type No	TPA***	
Load Voltage Range	2	220 VAC
	3	380 VAC
Max. Rated Load Current Range	5A	
Max. Surge Current (10ms)	50A	
Transient Overvoltage	2	600Vp
	3	800Vp
Max. ON-State Drop Voltage	1.5VAC	
Max. Leakage Current	5 mA	
Max. Turn - ON Time	10ms	
Max. Turn - OFF Time	10ms	
Operate Frequency	47~70Hz	
Max. Power Dissipation	1.5 W/A	
Min. OFF-State dv/dt	250V/ μ S	



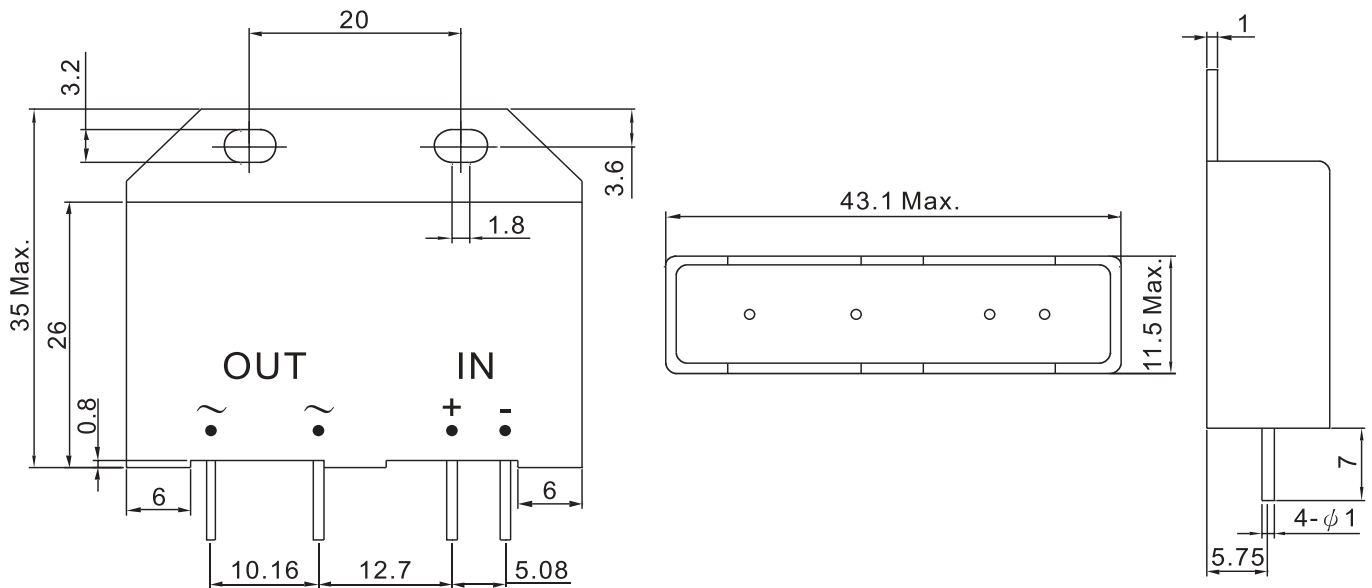
PhotoMOS-FET Relays
General-Purpose
Hi-A Grade $\geq 1A$
Hi-V Grade $\geq 600V$
Low Leakage Current
RF
Photo Coupler
Mos Driver

Output Characteristics	
Min. Insulation Resistance	1000M Ω
Dielectric Strength	2000 V.r.m.s.
Operating Temperature	-30°C ~+80°C
Storage Temperature	-40°C ~+100°C
Unit Weight	25g Max.

DC Output Characteristic



Dimensions : (Unit : mm)



TPD Series

D/D-Load Current : 5.0A

Features

- DC input, DC output
- Magnetism isolated
- Epoxy flooding, aluminium bottom radiator
- Power MOSFET output



Order Code:

TPD S 0 5

a b c d

- a : Model : TPD = DC Input, DC Output
 b : Input Voltage : S = 3~7 VDC ; H = 10~32 VDC
 c : Output Voltage : 0 = 50 VDC
 d : Rated Current : 5 = 5A

Specifications (DC Output)

Input Circuit		
Type	TPDS05	TPDH05
Input Voltage Range	3~7 VDC	10~32 VDC
Input Current	3~15mA	3~15mA
Min Release Voltage	1VDC	3 VDC

Output Characteristics(at20°C)	
Type No	TPD
Max. Load Voltage	50VDC
Max. Rated Load Current	5A
Max. Surge Current (10ms)	17.5A
Transient Overvoltage	55Vp
Max. ON-Resistance	0.01Ω
Max. Leakage Current	0.01mA
Max. Turn - ON Time	0.1ms
Max. Turn - OFF Time	0.5ms
Power Dissipation	0.25W



PhotoMOS-FET Relays
General-Purpose

PhotoMOS-FET Relays
Hi-A Grade ≥ 1A

PhotoMOS-FET Relays
Hi-V Grade ≥ 600V

PhotoMOS-FET Relays
Low Leakage Current

PhotoMOS-FET Relays
RF

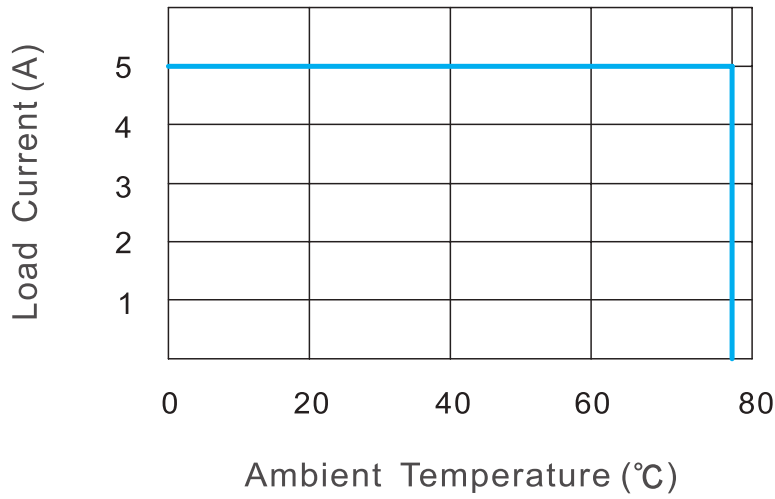
PhotoMOS-FET Relays
Photo Coupler

PhotoMOS-FET Relays
Mos Driver

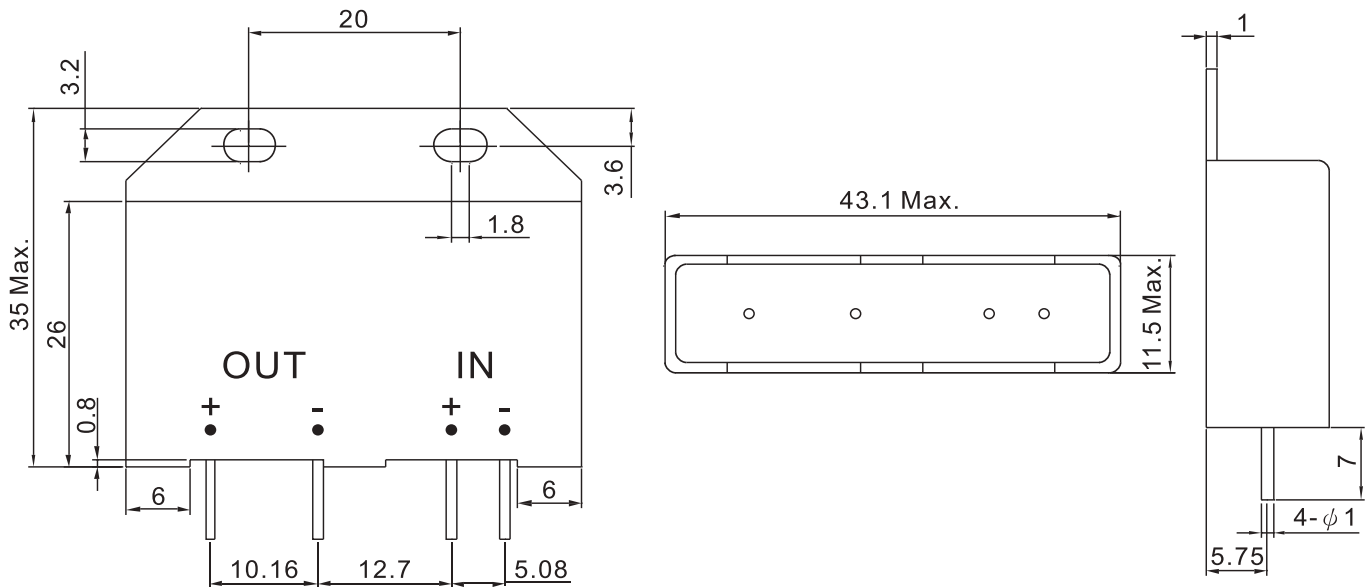
Solid State Relays

General Characteristics	
Min. Insulation Resistance	1000MΩ
Dielectric Strength	2000 V.r.m.s.
Operating Temperature	-30°C ~+80°C
Storage Temperature	-40°C ~+100°C
Unit Weight	25g Max.

DC Output Characteristic



Dimensions : (Unit : mm)



TL Series

DC Input & AC Output 8A/16A

Features

- High isolation voltage 4000 VAC between input and output
- 600VDC peak blocking Voltage
- Be suitable for 110/220VAC power voltage
- Random-on & Zero-on types are available
- UL Recognized

Applications

- Household appliance
- Programmable controller



Order Code:

TL 2 16 R - X
a b c d e

a : Model : TL = SIP 4 Pin Package
b : Output Voltage : 2 = 240VAC
c : Output Current : 08 = 8Amp ; 16 = 16Amp
d : Turn - on Type : Nil = Zero - on ; R = Random - on
e : Option : Nil = Standard, 1-9 = Special code

Absolute Maximum Rating:

Items		Symbol	Rating		Unit
			TL208(R)	TL216(R)	
Input	Forward Current	I _F	50		mA
	Peak Forward Current	I _{FP}	1		A
	Reverse Voltage	V _R	6		VAC
Output	Maximun Load Voltage	V _{omax}	280		VAC
	Off-state Output Voltage	V _{DRM}	600		VDC
	On-state Output Current	I _{T(RMS)}	8	16	A
	Non-repeative Sudge Current	I _{TSM}	80	160	A
I/O Isolation Voltage		V _{iso}	4000		VAC
Operating Temperature		T _{opr}	-25~+100		°C
Storage Temperature		T _{stg}	-35~+125		°C

Electrical Characteristics:

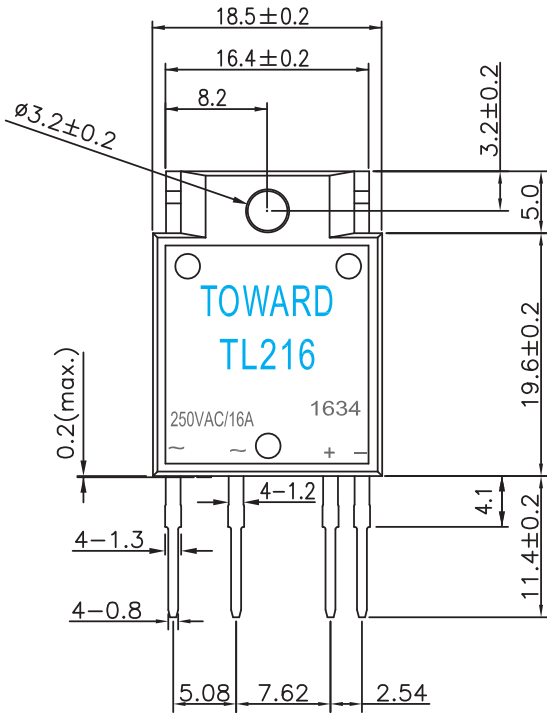
Items		Symbol	MIN.	TYP.	MAX.	Unit	Conditions
Input	Forward Voltage	V _F	-	1.18	1.4	V	I _F =10mA
	Reverse Current	I _R	-	-	10	μA	V _R =5V
Output	Leakage Voltage Range	V _O	35	-	280	VAC	
	Peak Leakage Current	I _{DRM}	-	-	100	μA	V _{DRM} =600V
	On-state Voltage	V _{TM}	-	-	1.5	V	I _T =Rated IT
	Hold Current	I _H	-	-	50	mA	V _{DRM} =600V/√2
	Rise rate of off-state	dv/dt	30	-	-	V/μS	V _{DRM} =600V/√2
Minimum trigger current		I _{FT}	-	-	10	mA	V _O =6V
Recovery Input Voltage		V _{F OFF}	0.5	-	-	V	
I/O Isolation Resistance		R _{iso}	10 ¹⁰	-	-	Ω	DC=500V
Turn-on Time (Random-on)		T _{ON}	-	-	1	μS	I _F =20mA
Turn-on Time (Zero-on)		T _{ON}	-	-	10	mS	-
Turn-off Time		T _{OFF}	-	-	10	mS	-

Note:Recommended trigger current is between 10mA and 20mA.



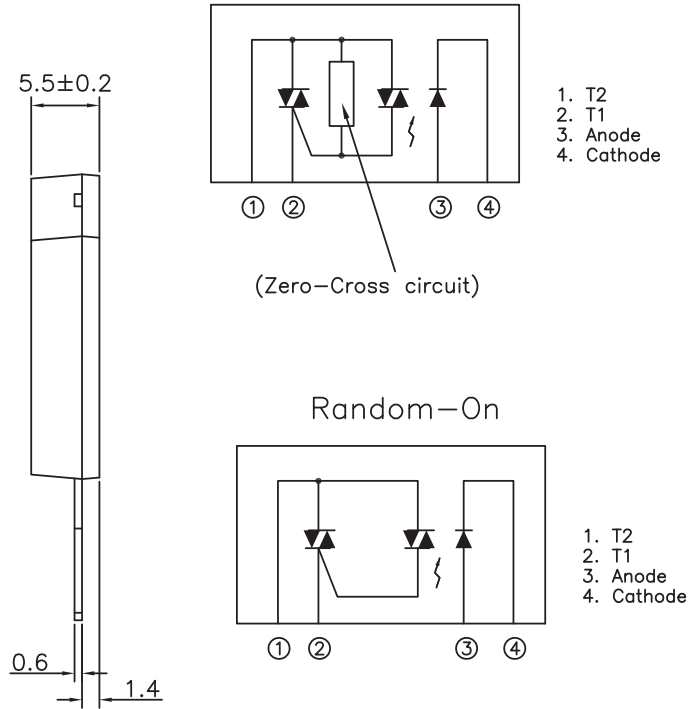
Dimensions : (Unit : mm)

Dimensions (mm)



Equivalent Circuit(Top view)

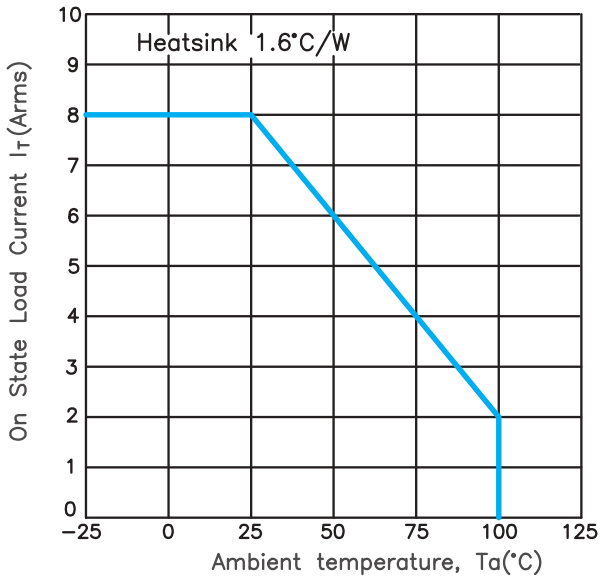
Zero-On



REFERENCE DATA :

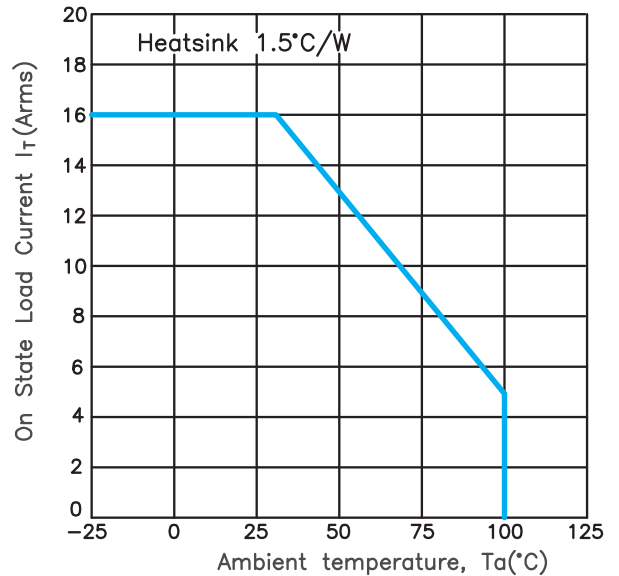
TL208

Mximum Load Current Vs. Ambient temperature



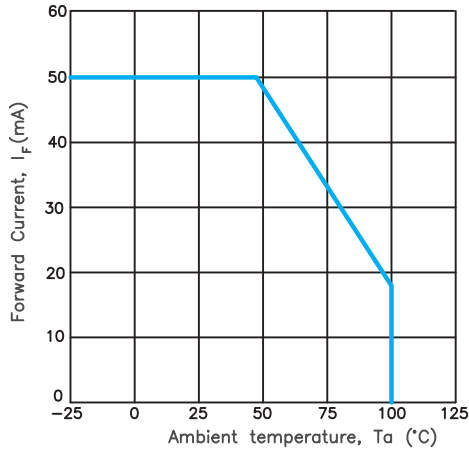
TL216

Mximum Load Current Vs. Ambient temperature

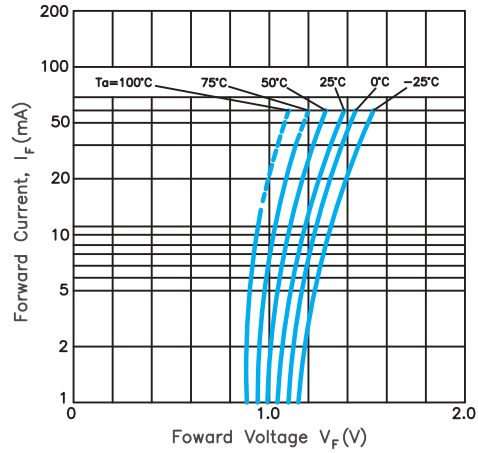




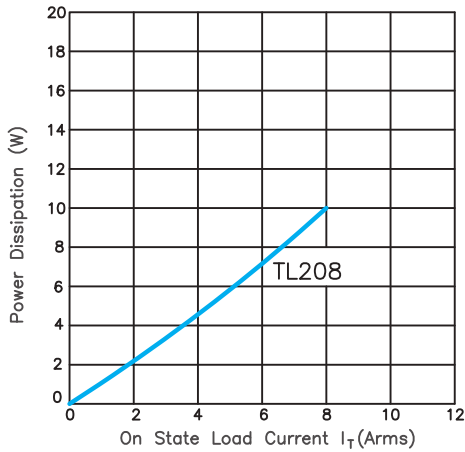
Forward Current Vs. Ambient temperature



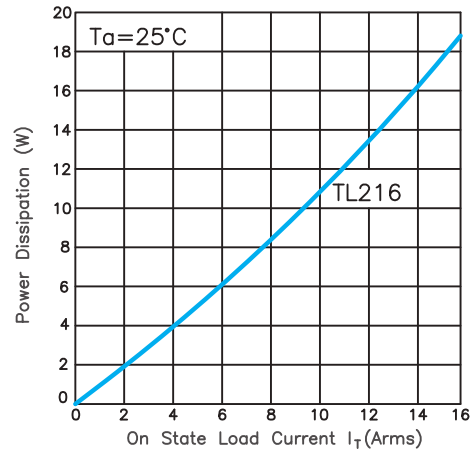
Forward Current Vs. Forward Voltage



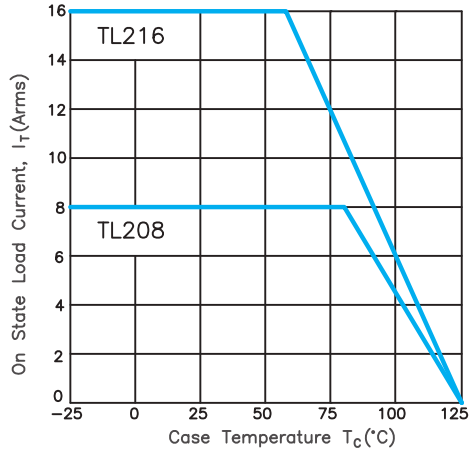
On State Power Dissipation Vs. On State Load Current



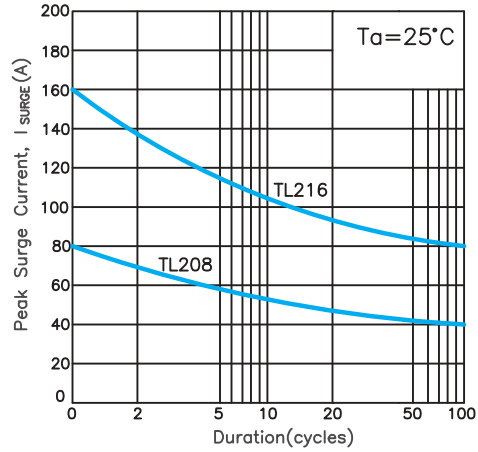
On State Power Dissipation Vs. On State Load Current



Maximum Load Current Vs. Case Temperature

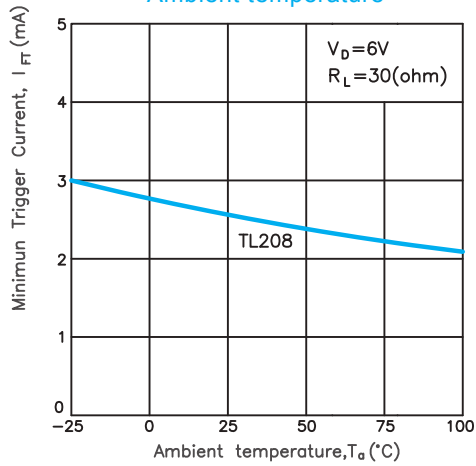


Peak Surge Current V.S Duration (Non Repetitive)

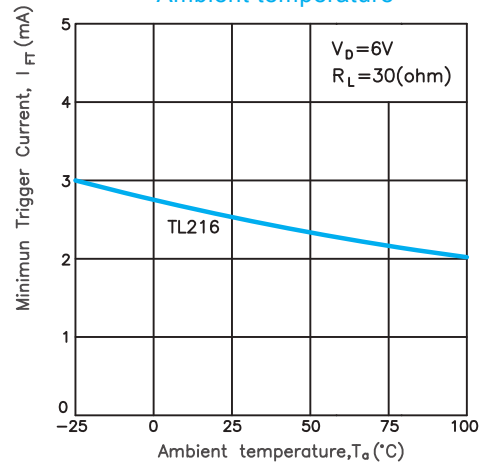




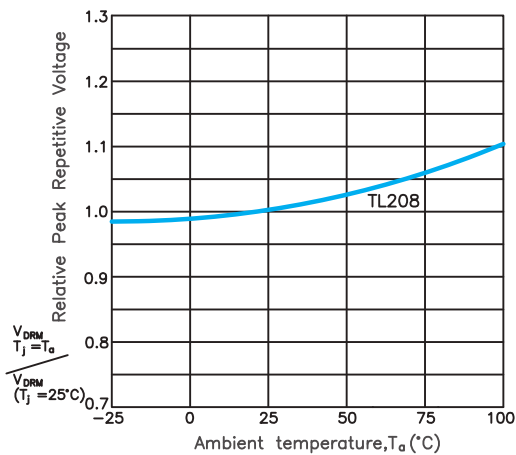
Minimum Trigger Current Vs. Ambient temperature



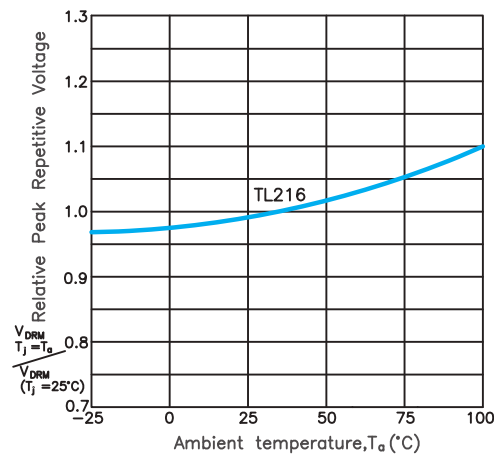
Minimum Trigger Current Vs. Ambient temperature



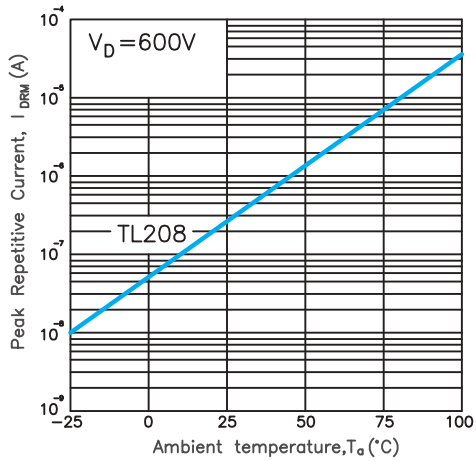
Relative Peak Repetitive Voltage Vs. Ambient Temperature



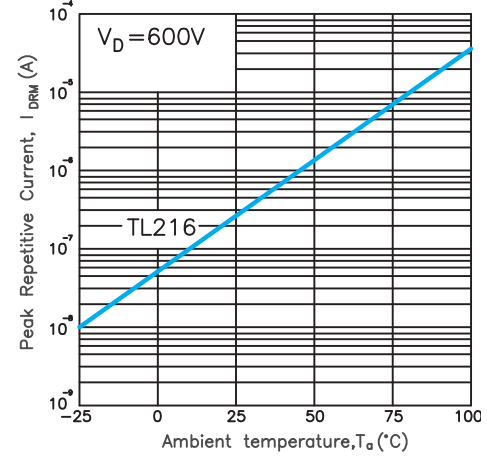
Relative Peak Repetitive Voltage Vs. Ambient Temperature



Peak Repetitive Current Vs. Ambient Temperature



Peak Repetitive Current V.S Ambient Temperature



PhotoMOS-FET Relays
General Purpose
Hi-A Grade ≥ 1A

PhotoMOS-FET Relays
Hi-V Grade ≥ 600V

PhotoMOS-FET Relays
Low Leakage Current

RF

PhotoMOS-FET Relays
Photo Coupler

PhotoMOS-FET Relays
Mos Driver

Solid State Relays



TDA/TAA Series *D/A·A/A·Load Current :10~40A*

Features

- Optically isolated;AC output
- Input LED indicator
- High dv/dt and high blocking voltage
- TTL and CMOS compatible control
- Zero voltage turn-on, zero current turn-off (minizes EMI/RFI)
- High surge rating allows lamp and motor load switching
- Output snubber circuit protection
- VDE recognized



Order Code:

TDA 2 25 * * * *
a b c d e f g

a : Model : TDA = DC Input, AC Output ; TAA = AC Input, AC Output
b : Output Voltage : 2 = 240VAC ; 3 = 380VAC ; 4 = 480VAC
c : Rated Current : 10A, 15A, 25A, 40A
d : Turn-On Type : NIL = Zero-On
e : Special Code : NIL = With LED ; N = Without LED
f : Option : NIL = Without Safety Cover ; C = With Safety Cover
g : Terminal : NIL = Without Terminal ; T = With Terminal

Input

Type	TDA	TAA
Input Voltage Range	4~32 VDC	90~280 VAC
Input Current	6~17mA	7~22mA
Min Release Voltage	1VDC	20 VAC

Output Load

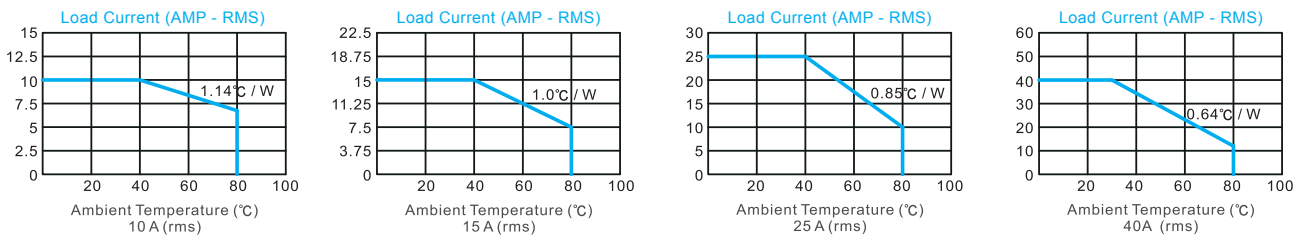
Type NO	10A	15A	25A	40A
Max. Rated Load Current Range	10A	15A	25A	40A
Max. Surge Current (10ms)	100A	150A	250A	400A
Load Voltage Range	2	24~280 VAC		
	3	48~380 VAC		
	4	48~480 VAC		
Transient Overvoltage	2	600Vp		
	3	800Vp		
	4	1000Vp		
Max. ON-State Drop Voltage	1.8VAC			
Max. Leakage Current	10 mA			
Max. Turn - ON Time	Zero-on:10ms			
Max. Turn - OFF Time	30ms			
Operate Frequency	47~70Hz			
Max. Power Dissipation	2W/A			
Min. OFF-State dv/dt	250V/μS			



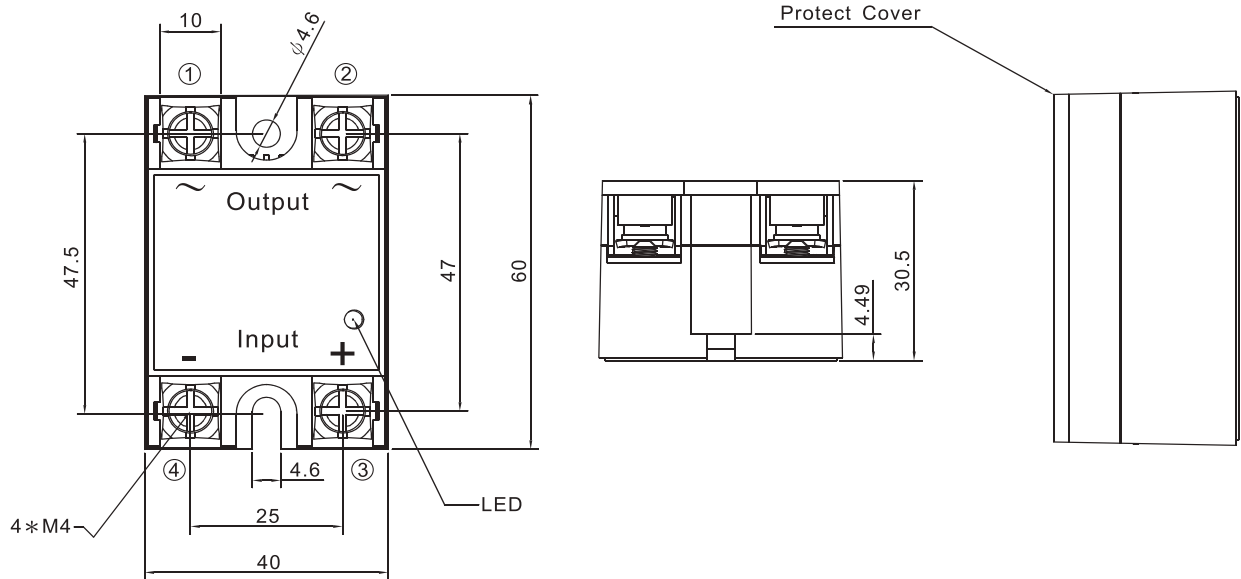
General Rating

Min. Insulation Resistance	1000MΩ
Insulation Between Input-Output	3500 VAC
Insulation Input-Output To Case	2000 VAC
Operating Temperature	-30°C ~+80°C
Storage Temperature	-40°C ~+100°C
Unit Weight	Approx 120g

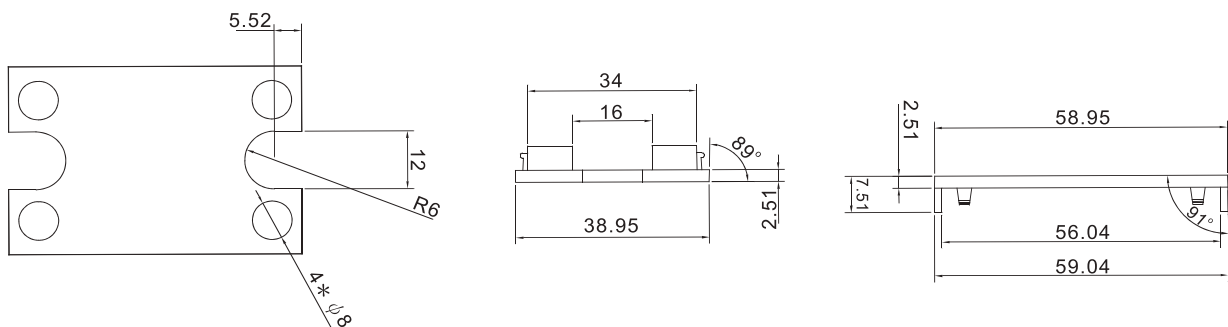
Load Current Derating Curve



Dimensions : (Unit : mm)



Protect Cover

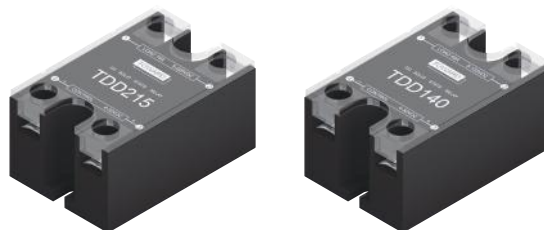


TDD Series

D/D-Load Current : 15~40A

Features

- Optically isolated;DC output
- Input LED indicator
- High dv/dt and high blocking voltage
- TTL and CMOS compatible control
- High surge rating allows lamp and motor load switching
- MOSFET output



Order Code:

TDD 1 40 * *

a b c d e

- a : Model : TDD = DC Input, DC Output
 b : Output Voltage : 1 = 100VDC ; 2 = 200VDC
 c : Rated Current : 15A, 25A, 40A
 d : Special Code : NIL - With LED ; N = Without LED
 e : Option : NIL = Without Safety Cover ; C = With Safety Cover

Input

Type	15A	25A	40A
Input Voltage Range	4~32 VDC		
Input Current	16~27mA		
Max Operate Voltage	4VDC		
Min Release Voltage	1VDC		

Output Load

Type NO		15A	25A	40A
Load Current Range	100VDC	5~100VDC		
	200VDC	5~200VDC		
Max. Rated Load Current Range		15A	25A	40A
Max. Surge Current (100ms)	100VDC	60	80	120
	200VDC	60	-	-
ON-Resistance(Ω)(Max.)	100VDC	0.12	0.06	0.04
	200VDC	0.12	-	-
Max. Leakage Current		10 μA		
Max. Turn - ON Time		3ms		
Max. Turn - OFF Time		3ms		

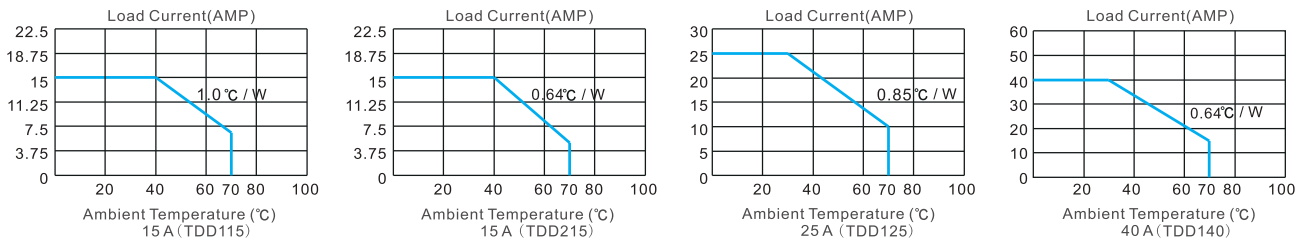


PhotoMOS-FET Relays
 General Purpose
 Hi-A Grade ≥ 1A
 Hi-V Grade ≥ 600V
 PhotoMOS-FET Relays
 Low Leakage Current
 RF
 Photo Coupler
 PhotoMOS-FET Relays
 Mos Driver
 Solid State Relays

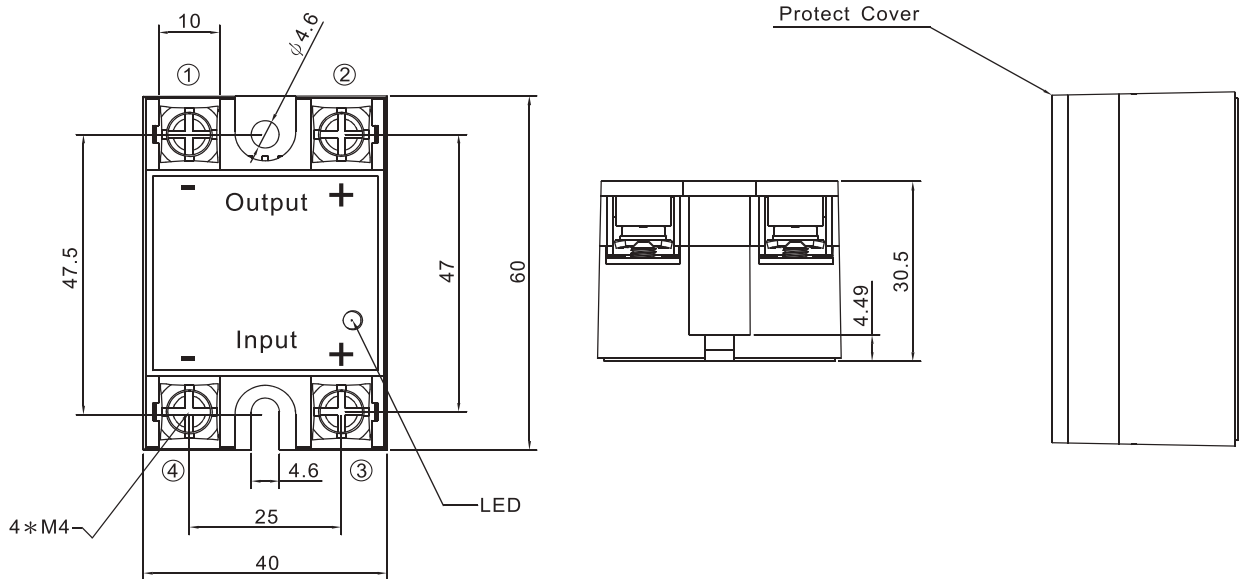
General Rating

Min. Insulation Resistance	1000MΩ
Insulation Between Input-Output	3500 VAC
Operating Temperature	-30°C ~+70°C
Storage Temperature	-40°C ~+100°C
Unit Weight	Approx 120g

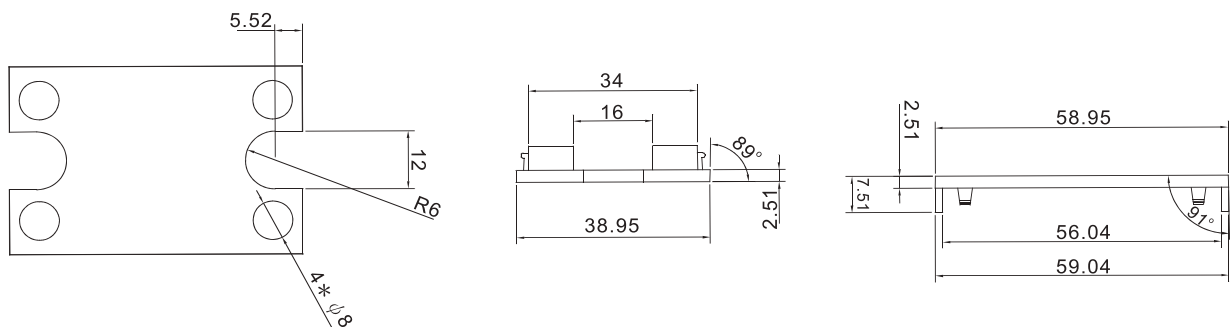
Load Current Derating Curve



Dimensions : (Unit : mm)



Protect Cover





TDB Series

D/A·Normal Close Type· Load Current :10~40A

Features

- Optically isolated;AC output;Normal Close type
- Input LED indicator
- High dv/dt and high blocking voltage
- TTL and CMOS compatible control
- Zero current turn-off (minizes EMI/RFI)
- High surge rating allows lamp and motor load switching
- Output snubber circuit protection



Order Code:

TDB 2 25 R * *

a b c d e f

- a : Model : TDB = DC Input, AC Output ; Normal close type
 b : Output Voltage : 2 = 240VAC
 c : Rated Current : 10A, 15A, 25A, 40A
 d : Turn-On Type : NIL = Zero-On ; R = Random-On
 e : Special Code : NIL = With LED ; N = Without LED
 f : Option : NIL = Without Safety Cover ; C = With Safety Cover

Input

Type	TDB
Input Voltage Range	4~32 VDC
Input Current	1.5~4.0mA
Min Release Voltage	1VDC

Output Load

Type NO	10A	15A	25A	40A
Max. Rated Load Current Range	10A	15A	25A	40A
Max. Surge Current (10ms)	100A	150A	250A	400A
Load Voltage Range	24~280 VAC			
Transient Overvoltage	600Vp			
Max. ON-State Drop Voltage	1.6VAC			
Max. Leakage Current	10 mA			
Max. Turn - ON Time	Random-on:1ms		Zero-on:10ms	
Max. Turn - OFF Time	10ms			
Operate Frequency	47~70Hz			
Max. Power Dissipation	2W/A			
Min. OFF-State dv/dt	250V/μS			

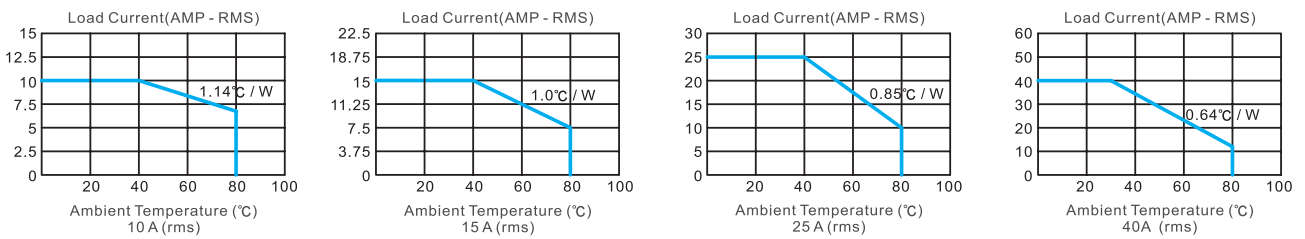


PhotoMOS-FET Relays
 General Purpose
 Hi-V Grade ≥ 1A
 Hi-V Grade ≥ 600V
 Low Leakage Current
 RF
 Photo Coupler
 Mos Driver
 Solid State Relays

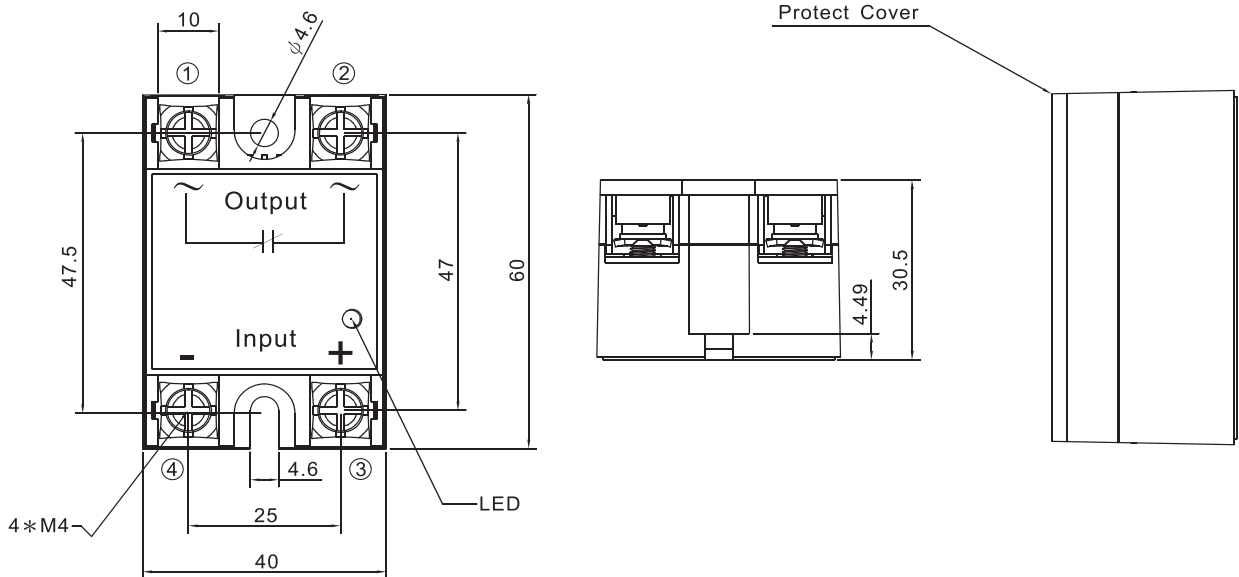
General Rating

Min. Insulation Resistance	1000MΩ
Insulation Between Input-Output	3500 VAC
Insulation Input-Output To Case	2000 VAC
Operating Temperature	-30°C ~+80°C
Storage Temperature	-40°C ~+100°C
Unit Weight	Approx 120g

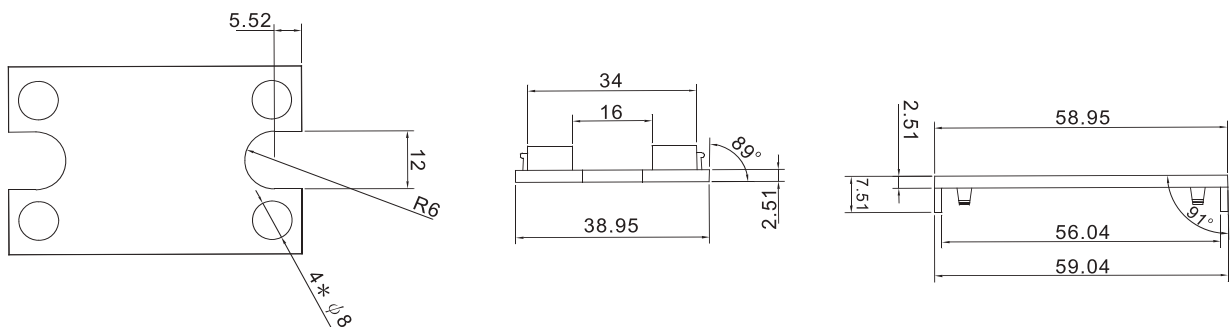
Load Current Derating Curve



Dimensions : (Unit : mm)



Protect Cover

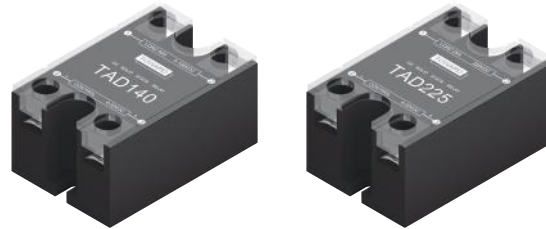


TAD Series

A/D·Load Current : 10~40A

Features

- Optically isolated; AC output; DC output
- Input LED indicator
- High dv/dt and high blocking voltage
- MOSFET output



Order Code:

TAD 2 25 * *

a b c d e

- a : Model : TAD = AC Input, DC Output
 b : Output Voltage : 1 = 100VDC ; 2 = 200VDC
 c : Rated Current : 10A, 15A, 25A, 40A
 d : Special Code : NIL - With LED ; N = Without LED
 e : Option : NIL = Without Safety Cover ; C = With Safety Cover

Input

Type	10A	15A	25A	40A
Input Voltage Range	90~280 VAC			
Input Current	1.0~7.0mA			
Max Operate Voltage	90VAC			
Min Release Voltage	20VDC			

Output Load

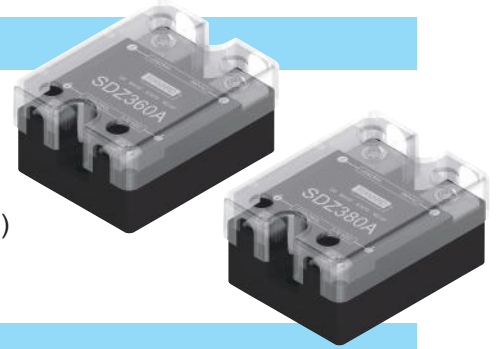
Type NO		10A	15A	25A	40A
Load Current Range (VAC)	100VDC	5~100VDC			
	200VDC	5~200VDC			
Max. Rated Load Current Range		10A	15A	25A	40A
Max. Surge Current (100ms)	100VDC	30	60	80	120
	200VDC	30	60	80	-
ON-Resistance(Ω)(Max.)	100VDC	0.20	0.12	0.06	0.05
	200VDC	0.20	0.12	0.06	-
Max. Leakage Current		10 μA			
Max. Turn - ON Time		15ms			
Max. Turn - OFF Time		30ms			

SDZ / SAZ (10-80A)

*D/A·A/A·Load
Current:10~80A*

Features

- Optically isolated;AC output
- Input LED indicator
- High dv/dt and high blocking voltage
- TTL and CMOS compatible control
- Zero voltage turn-on, zero current turn-off (minizes EMI/RFI)
- High surge rating allows lamp and motor load switching
- Output snubber circuit protection



Order Code:

SDZ 3 80A * * *

a b c d e f

a : Model : SDZ = DC Input, AC Output ; SAZ = AC input, AC output
 b : Output Voltage : 2 = 240VAC ; 3 = 380 VAC ; 6 = 600 VAC
 c : Rated Current : 10A, 15A, 20A, 25A, 40A, 50A, 60A, 80A
 d : Turn - On Type : NIL = Zero - On ; R = Random - On
 e : Special Code : NIL = With LED ; N = Without LED
 f : Option : NIL = Without Safety Cover ; C = With Safety Cover

Input

Type	SDZ	SAZ
Input Voltage Range	3~32 VDC	90~280 VAC
Input Current	5~15mA	3~20mA
Min Release Voltage	1VDC	25VAC

Output Load

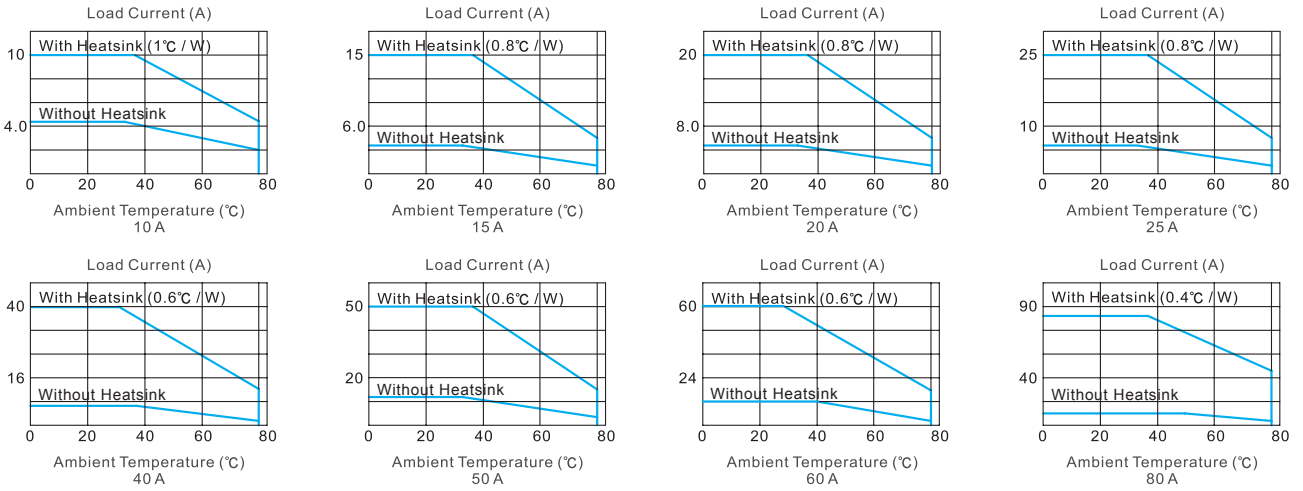
Type NO	10A	15A	20A	25A	40A	50A	60A	80A
Max. Rated Load Current Range	10A	15A	20A	25A	40A	50A	60A	80A
Max. Surge Current (10ms)	100A	150A	200A	250A	400A	520A	600A	840A
Load Voltage Range (VAC)	2	24~280	24~280	24~280	24~280	-	-	-
	3	48~400	48~400	48~400	48~400	48~400	48~400	48~400
	6	-	-	-	-	-	48~600	-
Transient Overvoltage (Vp)	2	600	600	600	600	600	-	-
	3	800	800	800	800	800	1200	800
	6	-	-	-	-	-	1200	-
Max. ON-State Drop Voltage (VAC)	2	2	2	2	2	1.8	2	2
Max. Leakage Current	10mA							
Max. Turn - ON Time	10ms							
Max. Turn - OFF Time	10ms							
Operate Frequency	47~70Hz							
Max. Power Dissipation	2 W/A	2 W/A	2 W/A	2 W/A	2 W/A	1.8 W/A	2 W/A	2 W/A
Min. OFF-State dv/dt	200V/μS							
Turn - On Type	Zero-on							

General Rating

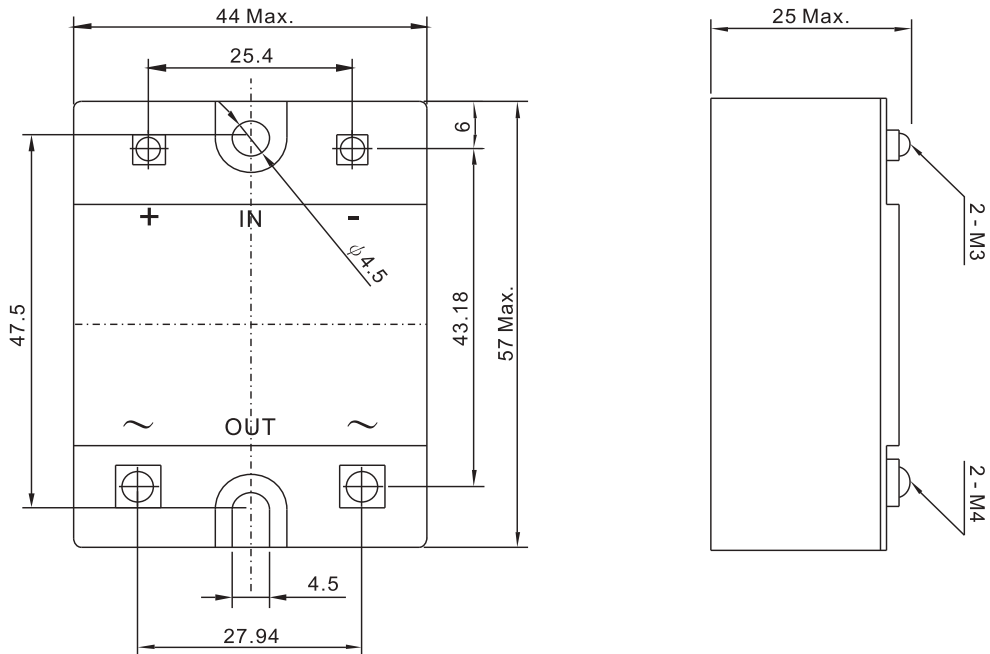
Min. Insulation Resistance	1000MΩ
Insulation Between Input-Output	2000 VAC
Insulation Input-Output To Case	2000 VAC
Operating Temperature	-30°C ~+80°C
Storage Temperature	-40°C ~+100°C
Unit Weight	Approx 120g



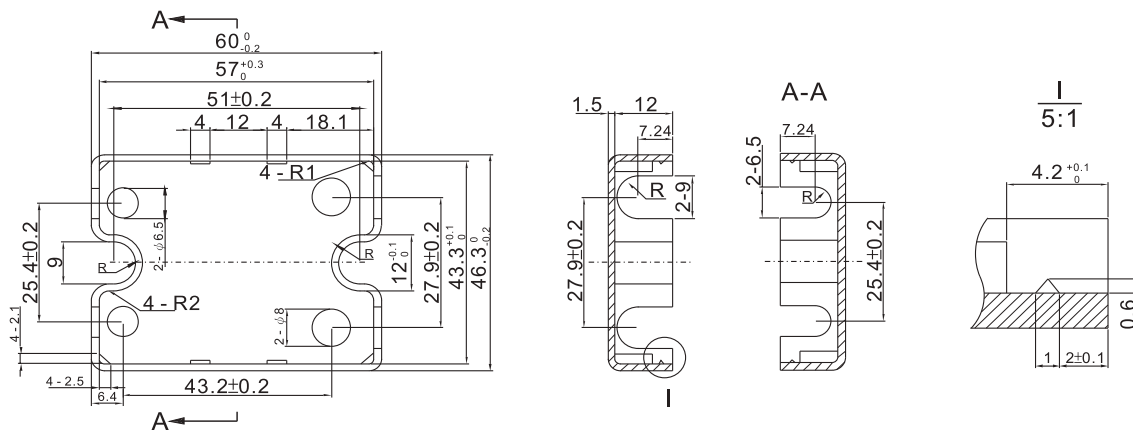
Load Current Derating Curve



Dimensions : (Unit : mm)



Safety Cover

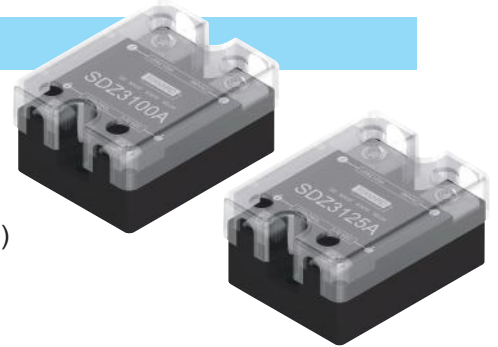


SDZ / SAZ (100-125A)

D/A·Load
Current:100~125A

Features

- Optically isolated;AC output
- Input LED indicator
- High dv/dt and high blocking voltage
- TTL and CMOS compatible control
- Zero voltage turn-on, zero current turn-off (minizes EMI/RFI)
- High surge rating allows lamp and motor load switching
- Output snubber circuit protection



Order Code:

SDZ 3 100A * *
a b c d e

a : Model : SDZ = DC Input, AC Output ; SAZ = AC input, AC output
b : Output Voltage : 3 = 380 VAC
c : Rated Current : 100A, 125A
d : Turn-On Type : NIL = Zero - On ; R = Random - On
e : Special Code : NIL = With LED ; N = Without LED

Input

Type	SDZ	SAZ
Input Voltage Range	3~32 VDC	90~280 VAC
Input Current	5~15mA	3~20mA
Min Release Voltage	1VDC	25VAC

Output Load

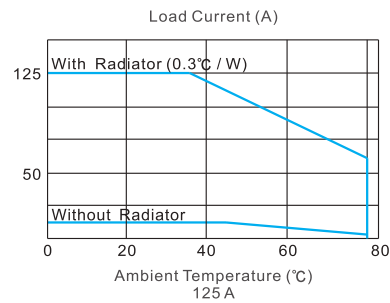
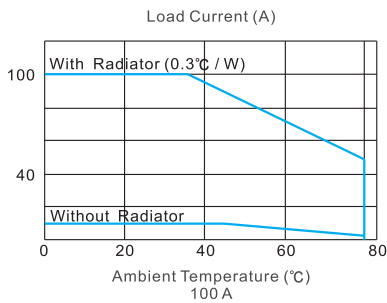
Type NO	100A	125A
Max. Rated Load Current Range	100A	125A
Max. Surge Current (10ms)	1000A	1200A
Load Voltage Range	380VAC	
Transient Overvoltage	1200Vp	
Max. ON-State Drop Voltage	2VAC	
Max. Leakage Current	10mA	
Max. Turn - ON Time	10ms (Zero-on)	
Max. Turn - OFF Time	10ms	
Operate Frequency	47~70Hz	
Max. Power Dissipation	2 W/A	
Min. OFF-State dv/dt	200V/μS	



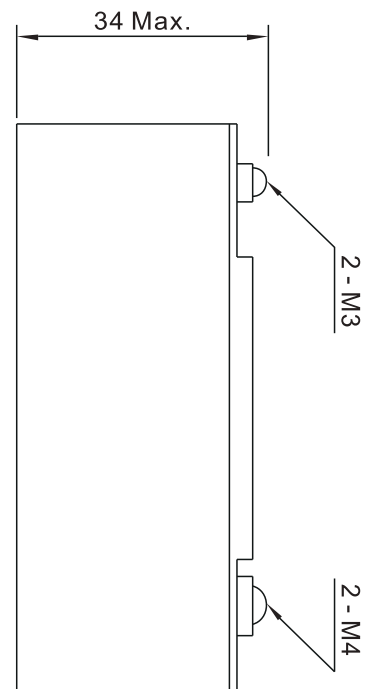
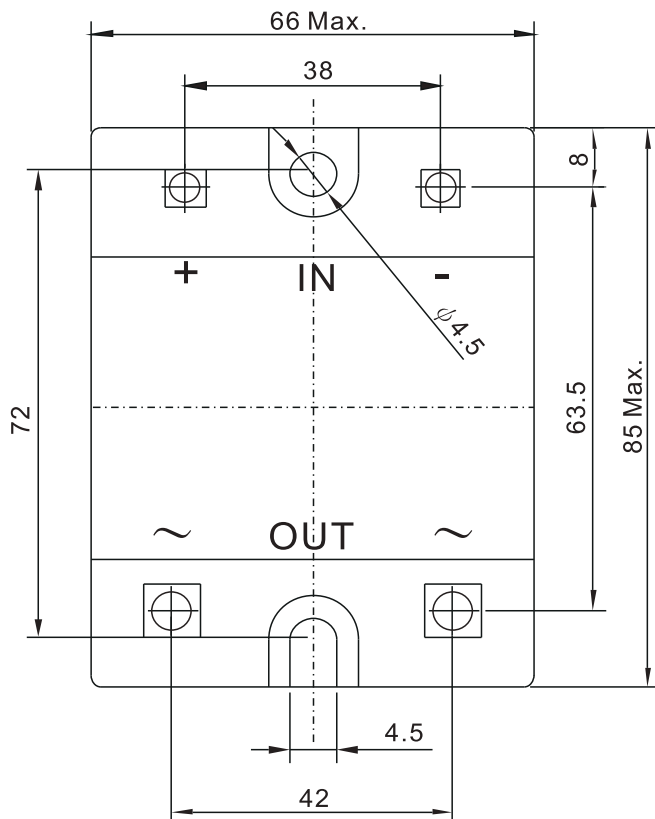
General Rating

Min. Insulation Resistance	1000MΩ
Insulation Between Input-Output	2000 VAC
Insulation Input-Output To Case	2000 VAC
Operating Temperature	-30°C ~+80°C
Storage Temperature	-40°C ~+100°C
Unit Weight	Approx 320g

Load Current Derating Curve



Dimensions : (Unit : mm)



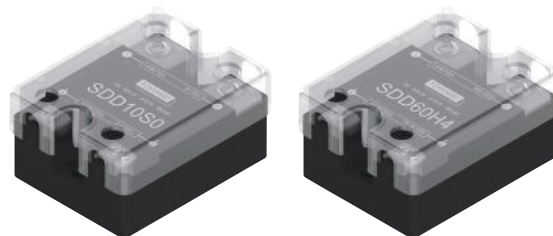
PhotomOS-FET Relays
 General Purpose
 Hi-A Grade ≥ 1A
 Hi-V Grade ≥ 600V
 Low Leakage Current
 PhotomOS-FET Relays
 RF
 Photo Coupler
 Mos Driver
 Solid State Relays

SDD Series

D/D-Load Current : 10~80A

Features

- Magnetism isolated;DC output
- Input LED indicator
- High dv/dt and high blocking voltage
- TTL and CMOS compatible control
- High surge rating allows lamp and motor load switching
- MOSFET/IGBT output



Order Code:

SDD 10 S 0 * *

a b c d e f

a : Model : SDD = DC Input, DC Output

b : Rated Current : 10A, 20A, 35A, 60A, 80A

c : Input Voltage : S = 4~7 VDC ; H = 10~32 VDC

d : Output Voltage : 0 = 50/80 VDC ; 2 = 220 VDC ; 4 = 400 VDC

e : Special Code : NIL = With LED ; N = Without LED

f : Option : NIL = With Safety Cover ; C = Without Safety Cover

Input

Type		10A-60A	80A
Input Voltage Range	S	4~7 VDC	4~7 VDC
	H	10~32 VDC	10~32 VDC
Max. Pick - Up Voltage	S	4V	4V
	H	10V	10V
Max. Input Current		20mA	20mA
Min. Release Voltage	S	1VDC	1VDC
	H	4VDC	2VDC

Output Load

Type NO		10A	20A	35A	60A	80A
Load Voltage Range(VDC)	0	50	50	50	50	80
	2	220	220	220	-	-
	4	400	400	400	400	-
Max. Rated Load Current(A)		10	20	35	60	80
Max. Surge Current (100ms)	0	50	60	80	120	150
	2	40	40	60	-	-
	4	40	80	120	160	-
Transient Overvoltage(Vp)	0	55	55	55	55	100
	2	400	500	500	-	-
	4	500	600	600	600	-
ON-Resistance(Ω) Or Drop Voltage(V)	0	0.05Ω	0.02Ω	0.01Ω	0.01Ω	0.5VDC
	2	0.1Ω	0.1Ω	0.1Ω	-	-
	4	0.12Ω	2VDC	2VDC	2VDC	-
Max. Leakage Current		10 μA	10 μA	10 μA	10 μA	1mA
Max. Turn - ON Time(ms)		0.1	0.1	0.1	0.1	0.1
Max. Turn - OFF Time(ms)		0.5	0.5	0.5	0.5	1.0

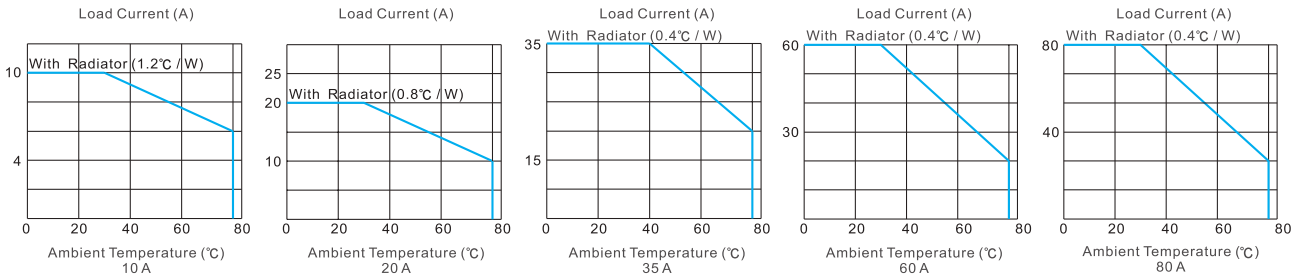


PhotoMOS-FET Relays
 General Purpose
 Hi-A Grade $\geq 1A$
 Hi-V Grade $\geq 600V$
 PhotoMOS-FET Relays
 Low Leakage Current
 RF
 Photo Coupler
 PhotoMOS-FET Relays
 Mos Driver

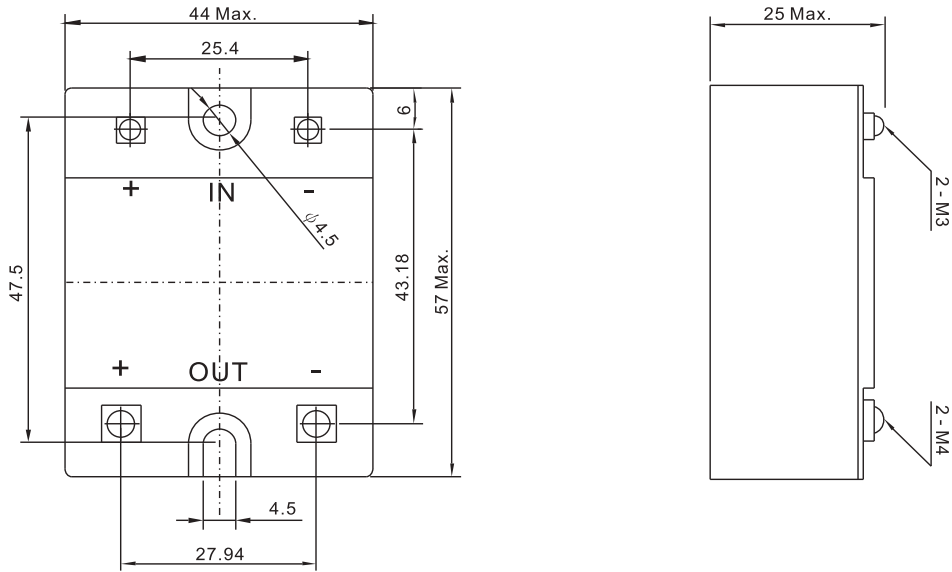
General Rating

Min. Insulation Resistance	1000M Ω
Dielectric Strength	1000 VAC
Operating Temperature	-30°C ~+80°C
Storage Temperature	-40°C ~+100°C
Unit Weight	Approx 120g

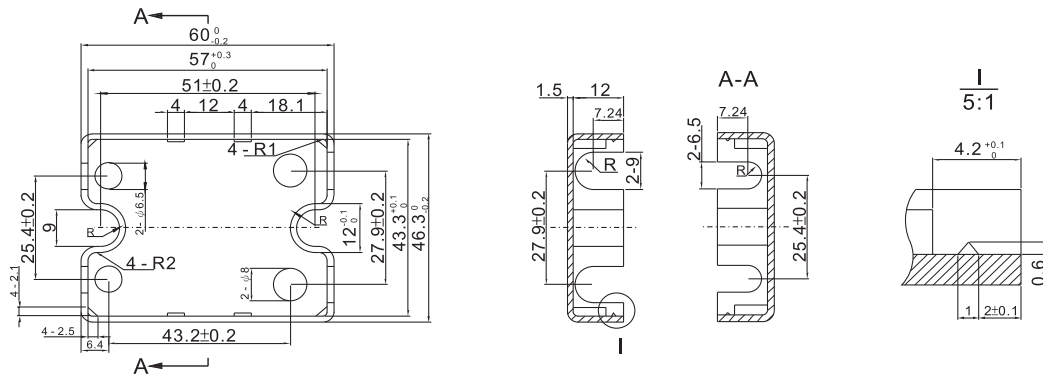
Load Current Derating Curve



Dimensions : (Unit : mm)



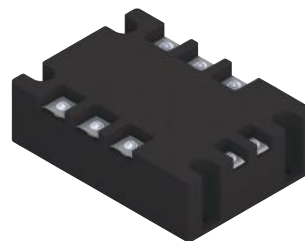
Safety Cover



SDT / SAT (10 - 40A)

Features

- DC/AC input, AC output
- With internal RC soak up network
- Zero voltage turn-on, zero current turn-off
- Optically isolated input and output
- Two-way SCR output
- Liquid epoxy-filled, metal(cu)base



Order Code:

SDT 3 ** A * * *
a b c d e f

a : Model : SDT = DC Input, AC output ; SAT = AC input, AC output
b : Output Voltage : 3 = 380 VAC
c : Rated Current : 10A, 20A, 40A
d : Turn-On Type : NIL = Zero-On
e : Special Code : NIL = With LED
f : Option : NIL = Without Safety Cover

Input

Type	SDT	SAT
Input Voltage Range	3~32 VDC	90~280 VAC
Input Current	≦ 50mA	≦ 20mA
Min Release Voltage	≧ 1VDC	≧ 25VAC

Output Load

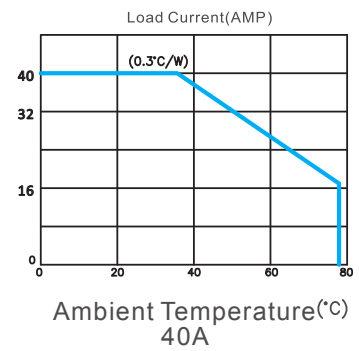
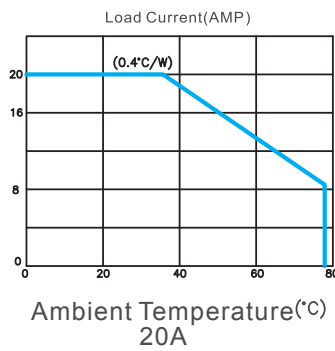
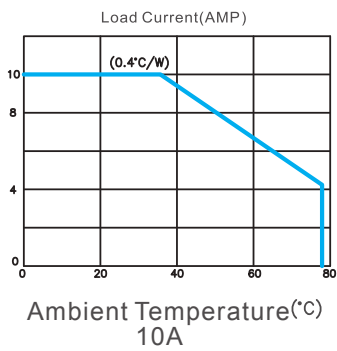
Type NO	10A	20A	40A
Max. Rated Load Current Range	10A	20A	40A
Max. Surge Current (10ms)	100A	200A	400A
Load Voltage Range	380VAC		
Transient Overvoltage	1000Vp		
Max. ON-State Drop Voltage	1.5VAC		
Max. Leakage Current	10mA		
Max. Turn - ON Time	≦ 10ms (Zero-on)		
Max. Turn - OFF Time	≦ 10ms		
Operate Frequency	47~400Hz		
Max. Power Dissipation	5 W/A		
Min. OFF-State dv/dt	200V/ μ S		



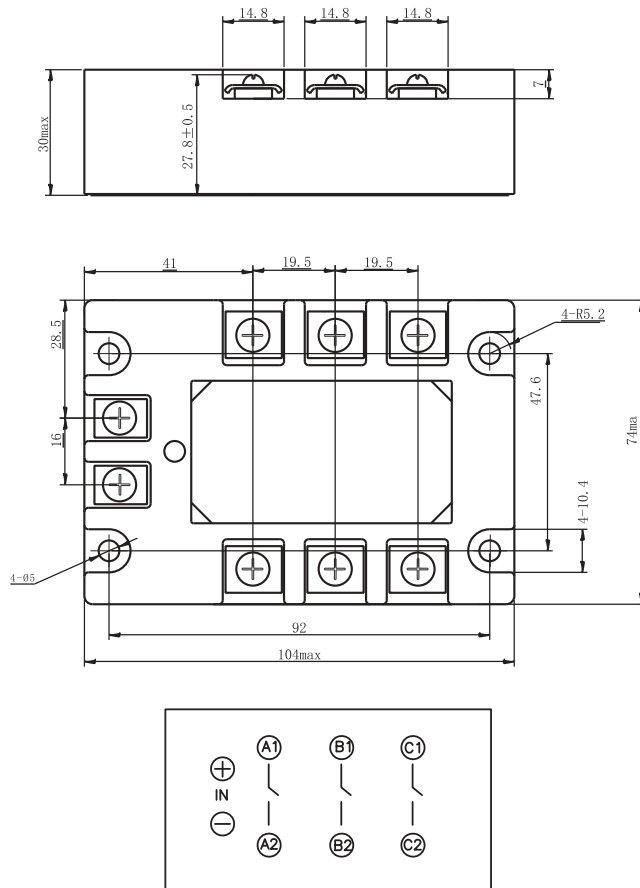
General Rating

Insulation Resistance	$\cong 1000M\Omega$
Insulation Between Input-Output	2000 VAC
Insulation Input-Output To Case	2000 VAC
Operating Temperature	-30°C ~+80°C
Storage Temperature	-40°C ~+100°C
Unit Weight	Approx 400g

Load Current Derating Curve



Dimensions : (Unit : mm)



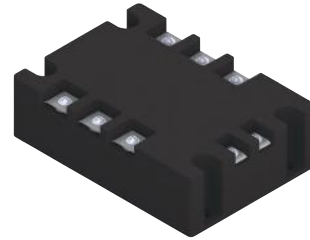
PhotomOS-FET Relays
 General-Purpose
 Hi-A Grade $\geq 1A$
 Hi-V Grade $\geq 600V$
 PhotomOS-FET Relays
 Low Leakage Current
 RF
 PhotomOS-FET Relays
 Photo Coupler
 Mos Driver

Solid State Relays

SDT / SAT (60 - 100A)

Features

- DC/AC input, AC output
- With internal RC soak up network
- Zero voltage turn-on, zero current turn-off
- Optically isolated input and output
- Two-way SCR output
- Liquid epoxy-filled, metal(cu)base



Order Code:

SDT 3 ** A * * *

a b c d e f

a : Model : SDT = DC Input, AC output ; SAT = AC input, AC output
 b : Output Voltage : 3 = 380 VAC
 c : Rated Current : 60A, 70A, 90A, 100A
 d : Turn-On Type : NIL = Zero-On
 e : Special Code : NIL = With LED
 f : Option : NIL = Without Safety Cover

Input

Type	SDT	SAT
Input Voltage Range	3~32 VDC	90~280 VAC
Input Current	≤ 50mA	≤ 20mA
Min Release Voltage	≥ 1VDC	≥ 25VAC

Output Load

Type NO	60A	70A	90A	100A
Max. Rated Load Current Range	60A	70A	90A	100A
Max. Surge Current (10ms)	600A	700A	840A	1000A
Load Voltage Range	380VAC			
Transient Overvoltage	800Vp			
Max. ON-State Drop Voltage	2VAC			
Max. Leakage Current	≤ 10mA			
Max. Turn - ON Time	≤ 10ms (Zero-on)			
Max. Turn - OFF Time	≤ 10ms			
Operate Frequency	47~400Hz			
Max. Power Dissipation	5 W/A			
Min. OFF-State dv/dt	200V/ μ S			

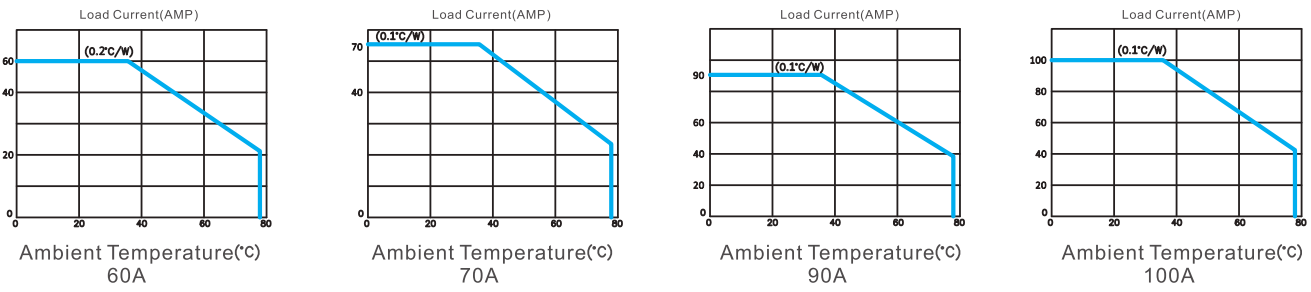


PhotoMOS-FET Relays
 General Purpose
 Hi-A Grade ≥ 1A
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 Low Leakage Current
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 Photo Coupler
 Mos Driver

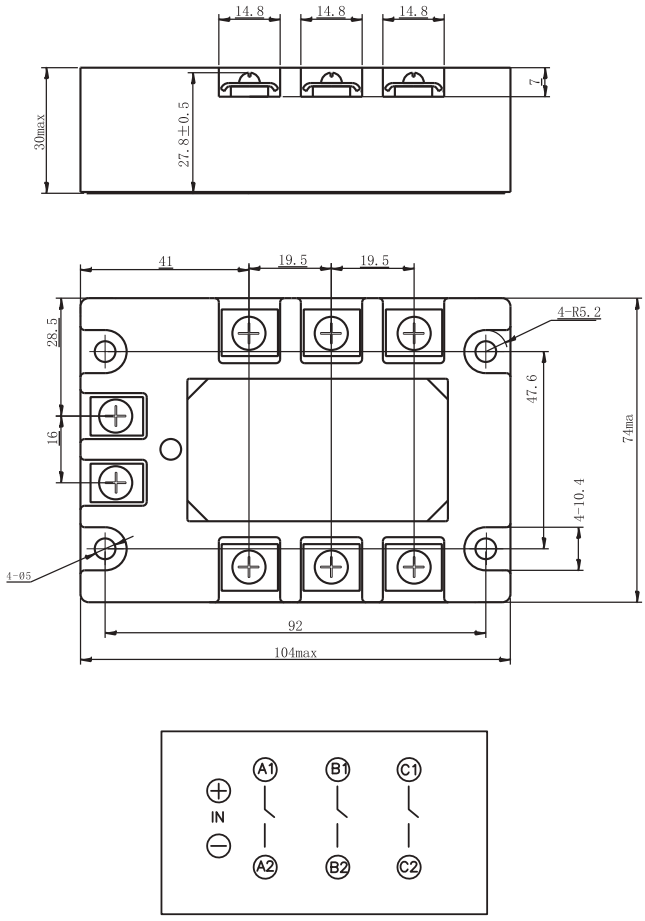
General Rating

Insulation Resistance	≧ 1000MΩ
Insulation Between Input-Output	2000 VAC
Insulation Input-Output To Case	2000 VAC
Operating Temperature	-30°C ~+80°C
Storage Temperature	-40°C ~+100°C
Unit Weight	Approx 400g

Load Current Derating Curve



Dimensions : (Unit : mm)



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